

令和6年度 ナノ社会人教育プログラム

コース1  
ナノマテリアル・ナノデバイスデザイン学

# Electron Theory in Solids

## Band Theory

### 固体中の電子

Koun SHIRAI

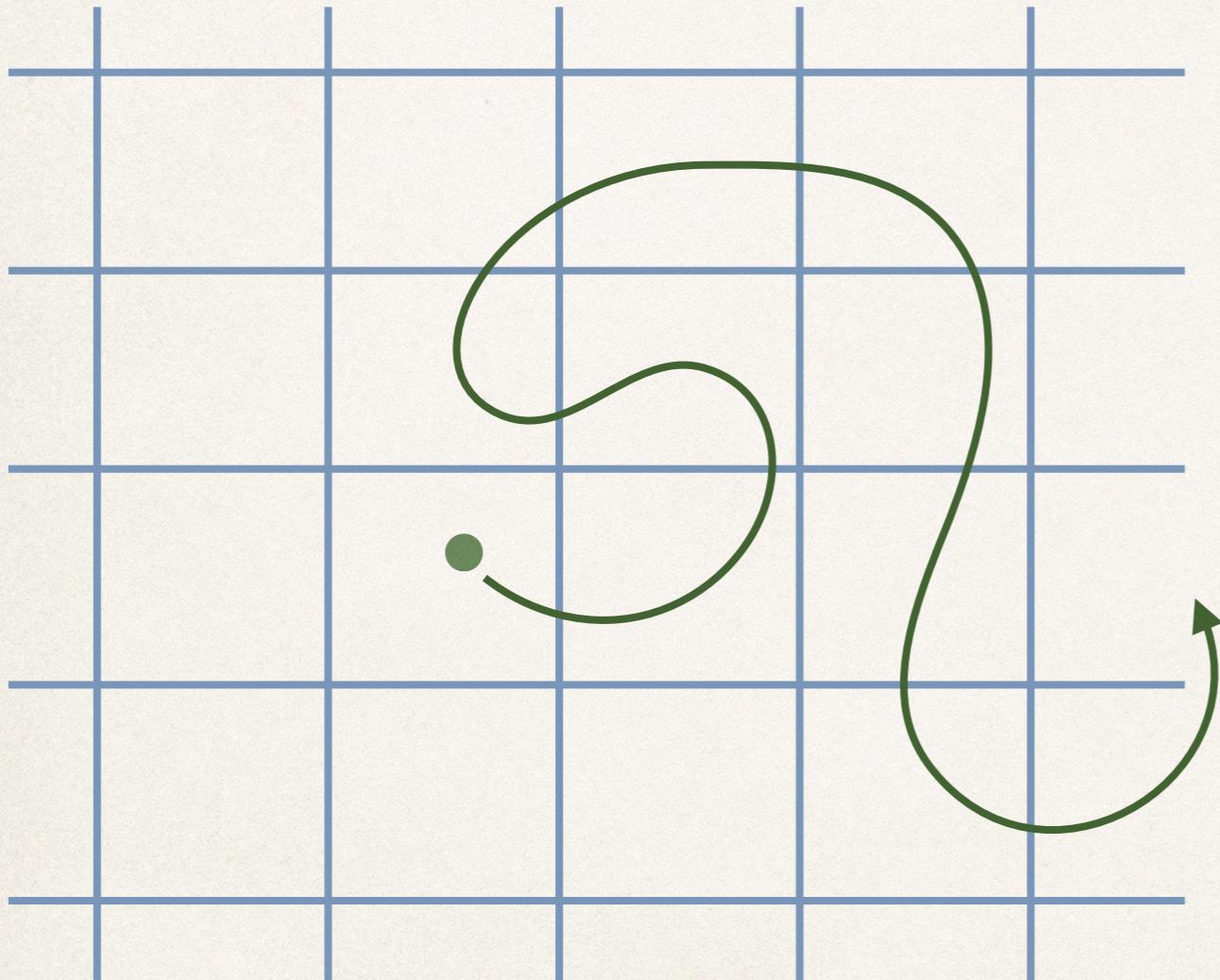
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Sanken Osaka University and Vietnam Japan University

# One-electron picture

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One electron



One-electron  
Schrödinger equation

$$\left( -\frac{\nabla^2}{2m} + \underline{V(\mathbf{r})} \right) \psi(\mathbf{r}) = \epsilon \psi(\mathbf{r})$$

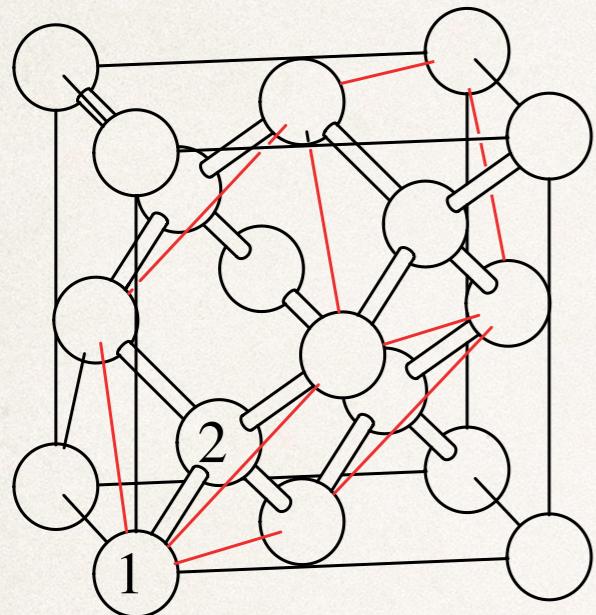
External potential

Forget the fact that the potential  $V(\mathbf{r})$  is created by electrons including the electron under consideration.

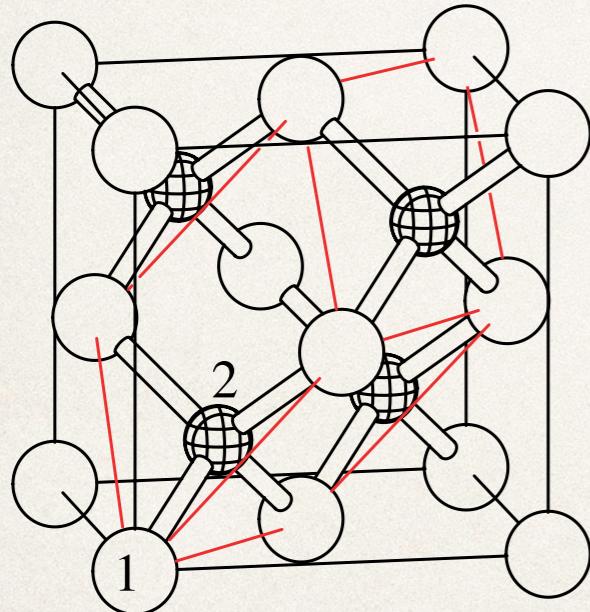
# 3.0 Preliminary

Microscopic structures of solids

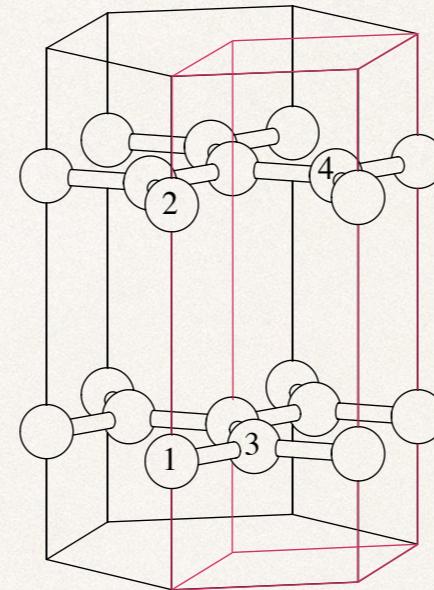
# Crystal structures



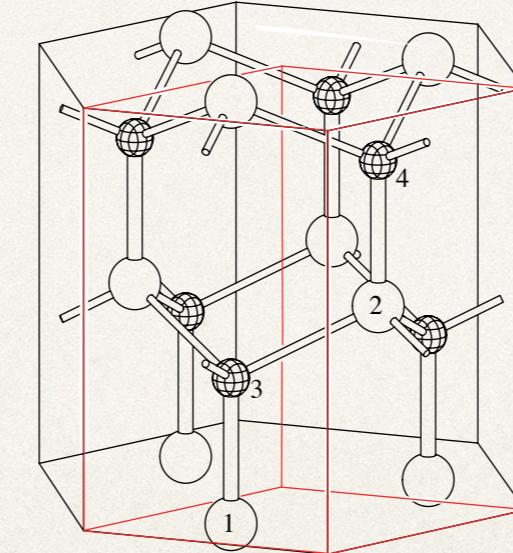
Diamond       $O_h^7$        $Fd\bar{3}m$



Zincblende       $T_d^2$        $T\bar{4}\bar{3}m$

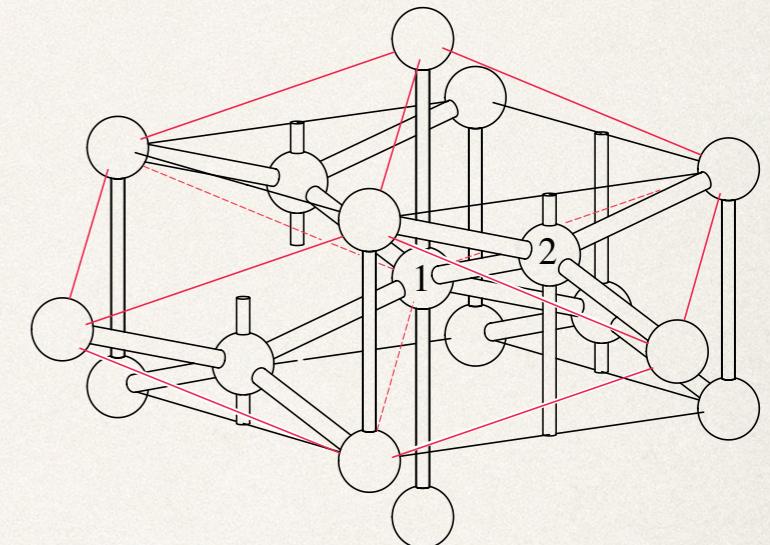


Graphite       $D_{6h}^4$   
 $P\bar{6}3/mmc$



Wurtzite       $C_{6v}^4$   
 $P\bar{6}3mc$

When  $c/a = \sqrt{2}$ , this is equivalent to diamond structure



$\beta$ -Tin       $D_{4h}^{19}$   
 $I\bar{4}1/amd$

6<sub>3</sub>: a six-fold screw along the c-axis  
 m: a mirror plane with normal (100)  
 c: glide plane in the c-axis with normal (120)

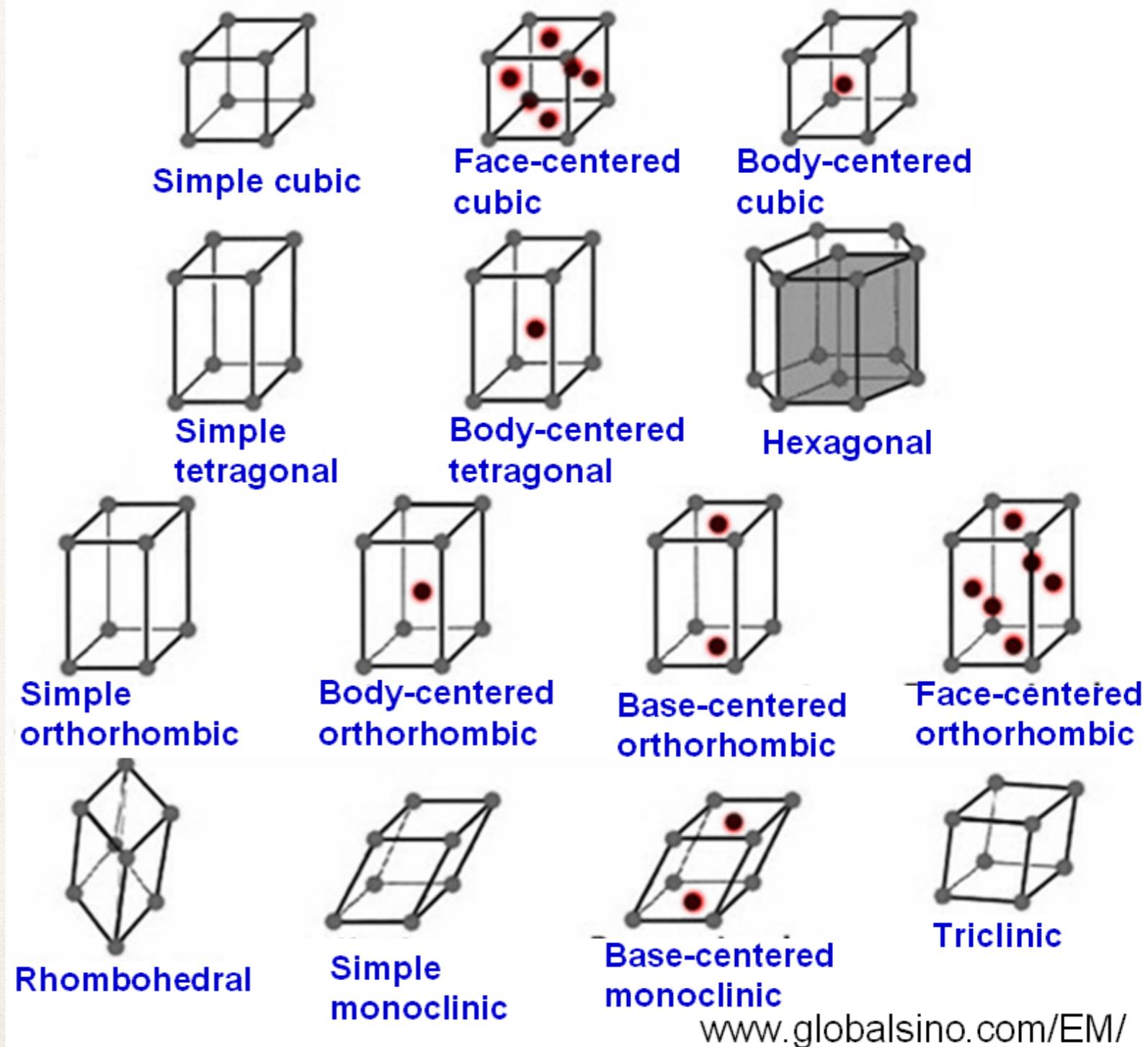
# Bravais Lattice

$$\mathbf{R} = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 + n_3 \mathbf{a}_3$$

$$\{\mathbf{a}_i\} \quad i = 1, 2, 3$$

Primitive lattice vectors

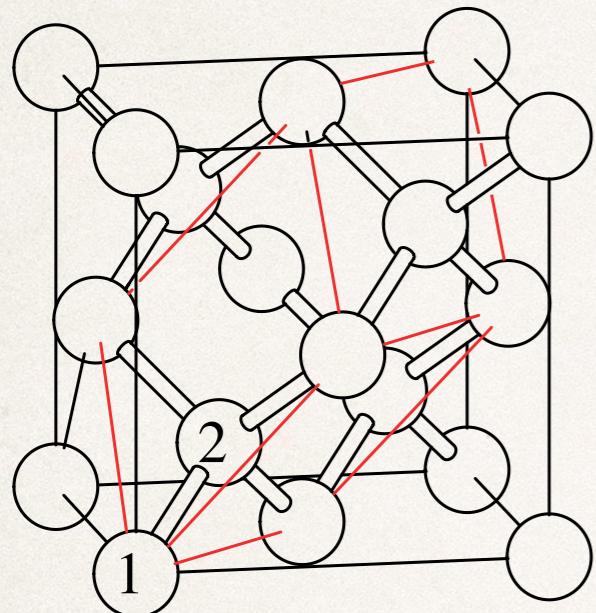
14 types of Bravais lattices



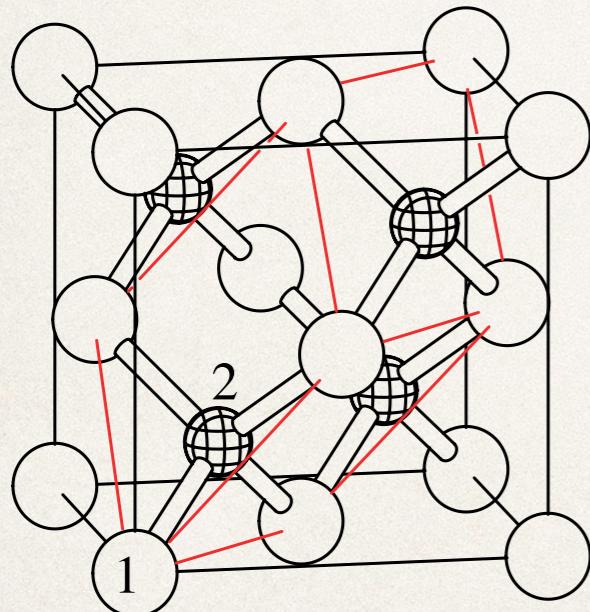
## 3.1 Bloch Theorem

Effects of lattice periodicity

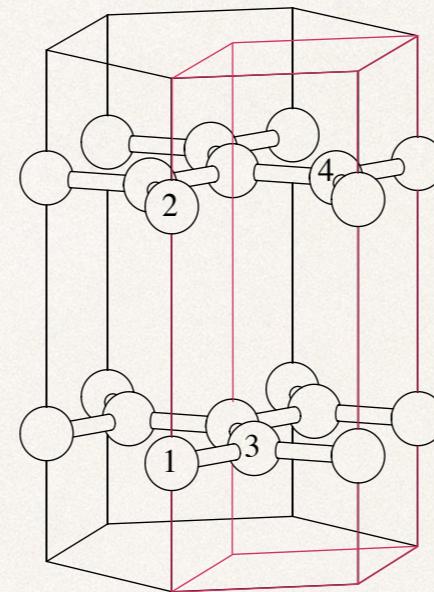
# Crystal structures



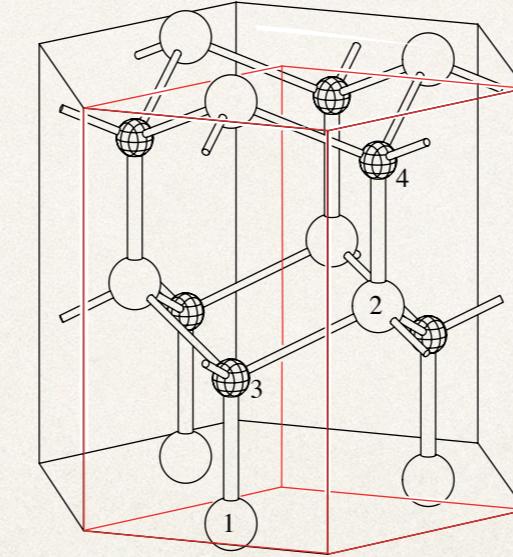
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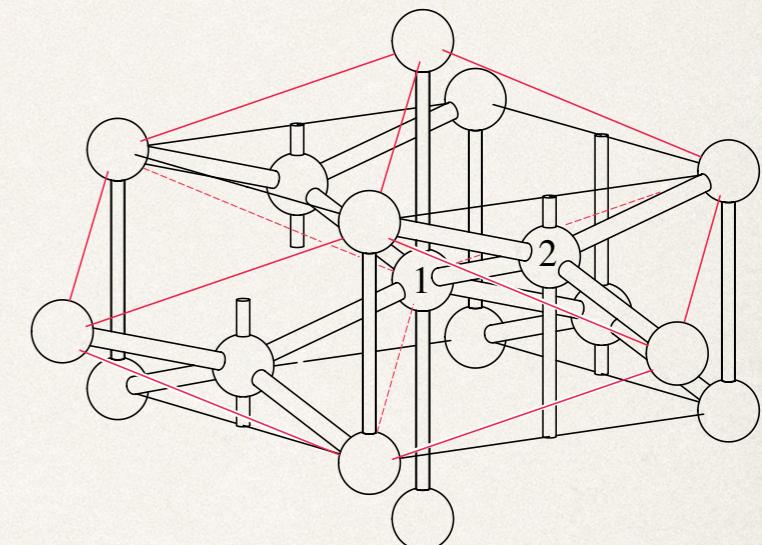


Graphite       $D_{6h}^4$   
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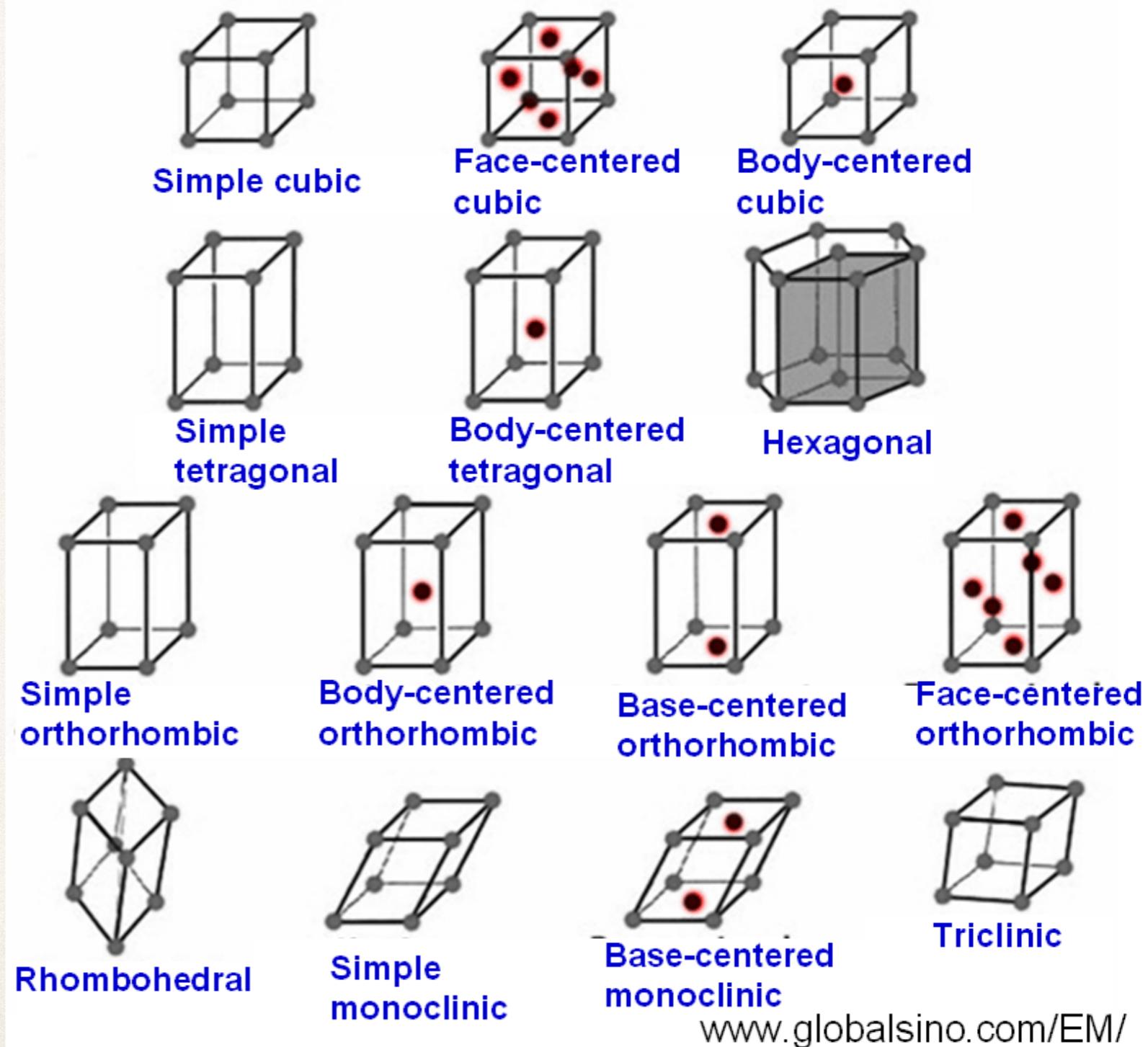
# Bravais Lattice

$$\mathbf{R} = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 + n_3 \mathbf{a}_3$$

$$\{\mathbf{a}_i\} \quad i = 1, 2, 3$$

Primitive lattice vectors

14 types of Bravais lattices



# Periodic structure

Real lattice vector

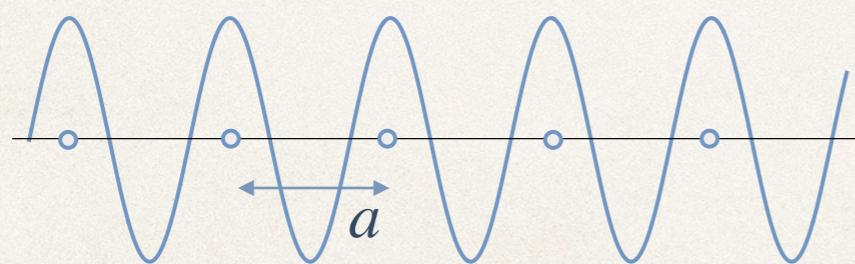
$$\mathbf{R} = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 + n_3 \mathbf{a}_3$$

$$\{\mathbf{a}_i\} \quad i = 1, 2, 3$$

Primitive lattice vectors

Potential

$$V(\mathbf{r}) = \sum_{\mathbf{K}} V(\mathbf{K}) \exp(i \mathbf{K} \cdot \mathbf{r})$$



$$K = \frac{2\pi}{a}$$

Reciprocal vector

$$\mathbf{K} = m_1 \mathbf{b}_1 + m_2 \mathbf{b}_2 + m_3 \mathbf{b}_3$$

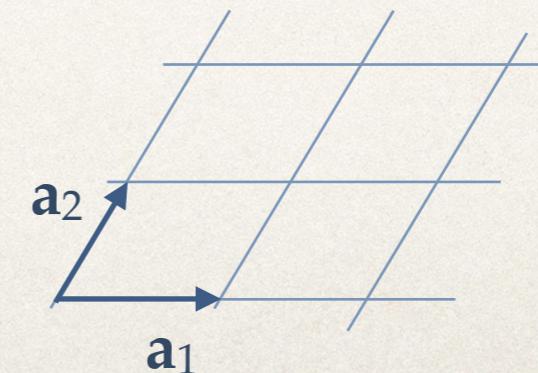
$$\{\mathbf{b}_i\} \quad \text{Primitive reciprocal vectors}$$

$$\mathbf{b}_i \cdot \mathbf{a}_j = 2\pi \delta_{i,j}$$

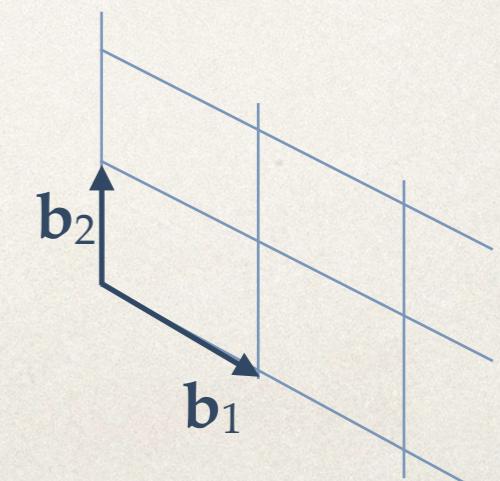
$$\mathbf{b}_i = 2\pi \frac{\mathbf{a}_j \times \mathbf{a}_k}{\mathbf{a}_i \times (\mathbf{a}_j \cdot \mathbf{a}_k)} = 2\pi \frac{\mathbf{a}_j \times \mathbf{a}_k}{\Omega}$$

$\Omega$ : Volume of the unit cell

Real space



Reciprocal space



## Wavefunctions

$$\psi(\mathbf{r}) = \sum_{\mathbf{K}} \psi(\mathbf{K}) \exp(i\mathbf{K} \cdot \mathbf{r}) ?$$

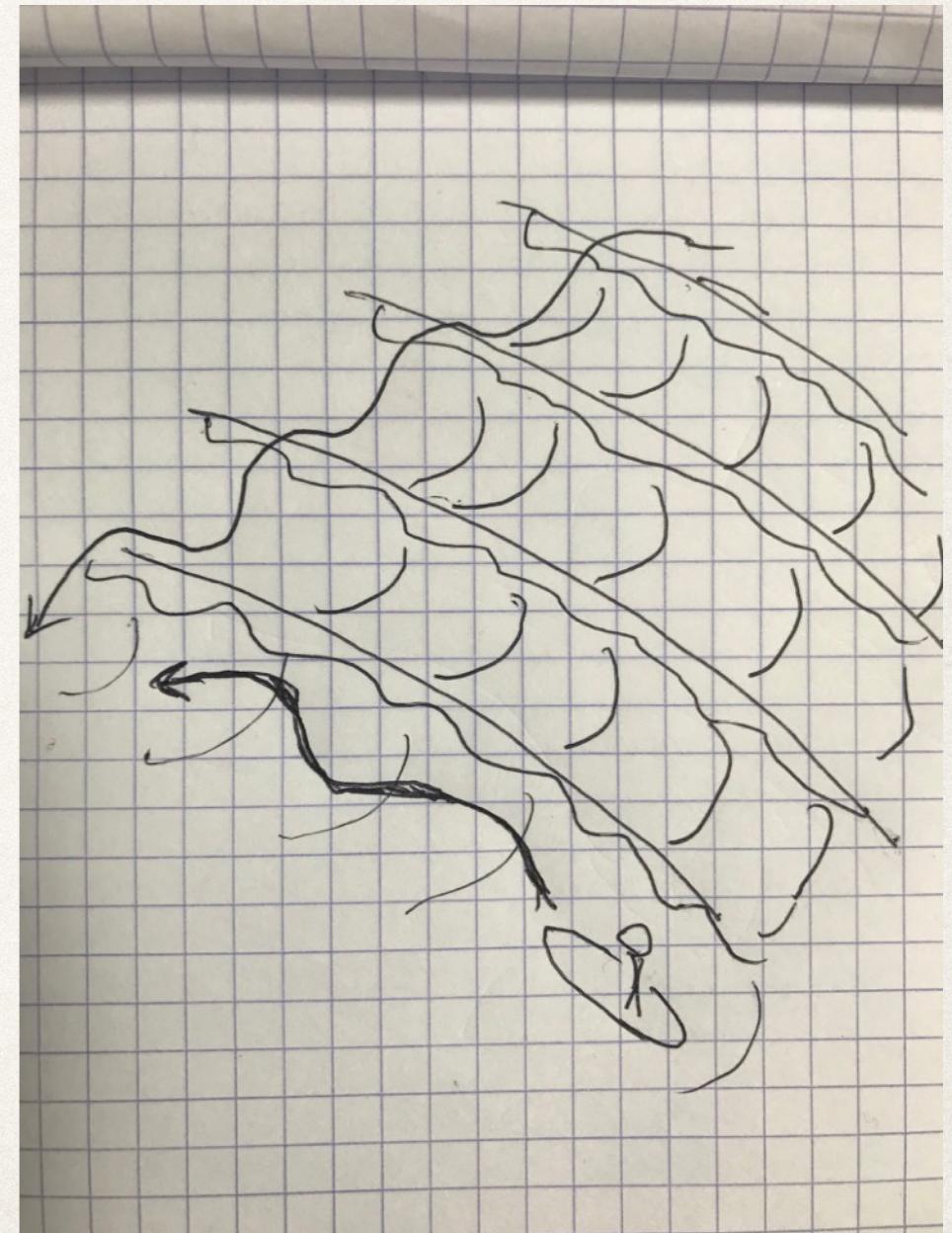
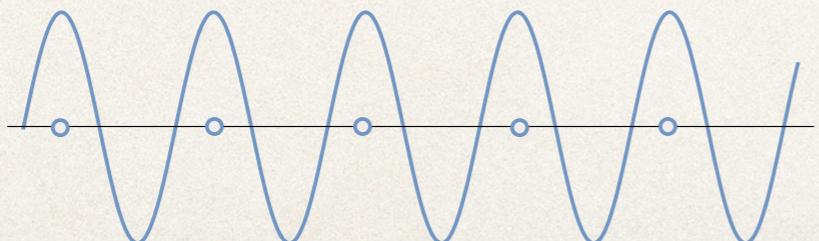


No!

However,

the charge density must have the lattice periodicity.

$$\rho(\mathbf{r}) = \psi(\mathbf{r})^* \psi(\mathbf{r})$$



# Bloch Theorem

Wavefunctions in a crystal

$$\psi_{\mathbf{k}}(\mathbf{r}) = \exp(i\mathbf{k} \cdot \mathbf{r})u_{\mathbf{k}}(\mathbf{r})$$

$u_{\mathbf{k}}(\mathbf{r})$  : periodic function of the lattice vector  $\mathbf{R}_j$

$$T(\mathbf{R})\psi_{\mathbf{k}}(\mathbf{r}) = \exp(i\mathbf{k} \cdot \mathbf{R})\psi_{\mathbf{k}}(\mathbf{r})$$

$T(\mathbf{R})$ : Translational operator

$$T(\mathbf{R})f(\mathbf{r}) = f(\mathbf{r} + \mathbf{R})$$

$$\begin{aligned} T(\mathbf{R})\psi_{\mathbf{k}}(\mathbf{r}) &= T(\mathbf{R})\exp(i\mathbf{k} \cdot \mathbf{r})u_{\mathbf{k}}(\mathbf{r}) \\ &= \exp(i\mathbf{k} \cdot (\mathbf{r} + \mathbf{R}))u_{\mathbf{k}}(\mathbf{r} + \mathbf{R}) \\ &= \exp(i\mathbf{k} \cdot \mathbf{R})\exp(i\mathbf{k} \cdot \mathbf{r})u_{\mathbf{k}}(\mathbf{r} + \mathbf{R}) \end{aligned}$$

$= \exp(i\mathbf{k} \cdot \mathbf{R})\psi_{\mathbf{k}}(\mathbf{r})$

$= \exp(i\mathbf{k} \cdot \mathbf{R})\exp(i\mathbf{k} \cdot \mathbf{r})u_{\mathbf{k}}(\mathbf{r})$

$u_{\mathbf{k}}(\mathbf{r} + \mathbf{R}) = u_{\mathbf{k}}(\mathbf{r})$

# Born-von Karman boundary conditions

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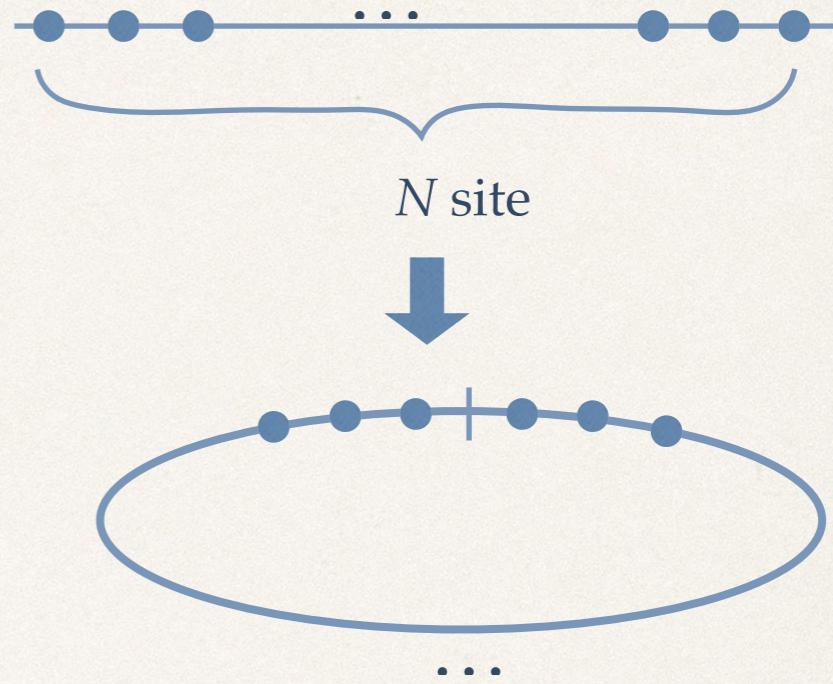
$$\mathbf{R} = n_1 \mathbf{a}_1 + n_2 \mathbf{a}_2 + n_3 \mathbf{a}_3$$

$$\{\mathbf{a}_i\} \quad i = 1, 2, 3$$

Primitive lattice vectors

$$\psi_{\mathbf{k}}(\mathbf{r} + N_i \mathbf{a}_i) = \exp(i N_i \mathbf{k} \cdot \mathbf{a}_i) \psi_{\mathbf{k}}(\mathbf{r})$$

$$\exp(i N k a) = 1 \quad \longrightarrow \quad k = \frac{m}{N} \frac{2\pi}{a} b$$



In 3D,

$$\mathbf{k} = \sum_{i=1}^3 \frac{m_i}{N_i} \mathbf{b}_i \quad \text{Reciprocal vectors}$$

$$\mathbf{K} = m_1 \mathbf{b}_1 + m_2 \mathbf{b}_2 + m_3 \mathbf{b}_3$$

$$\{\mathbf{b}_i\} \quad \text{Primitive reciprocal vectors}$$

$$\mathbf{b}_i \cdot \mathbf{a}_j = 2\pi \delta_{i,j}$$

$$\mathbf{b}_i = 2\pi \frac{\mathbf{a}_j \times \mathbf{a}_k}{\mathbf{a}_i \times (\mathbf{a}_j \cdot \mathbf{a}_k)} = 2\pi \frac{\mathbf{a}_j \times \mathbf{a}_k}{\Omega}$$

$\Omega$ : Volume of the unit cell

# Features of Bloch functions

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$$\psi_{\mathbf{k}}(\mathbf{r}) = \exp(i\mathbf{k} \cdot \mathbf{r})u_{\mathbf{k}}(\mathbf{r})$$

- $\mathbf{k}$  is a good quantum number.

Eigenfunctions must have Bloch functions.



However, Bloch functions are not necessarily the eigenfunctions.

- Eigenfunctions are expressed by a linear combination of Bloch functions with the same  $\mathbf{k}$ .  $\left\{ u_{\mathbf{k}}^j(\mathbf{r}) \right\}$
- Two eigenfunctions belonging to different  $\mathbf{k}$ 's are orthogonal each other.

$\varepsilon(\mathbf{k})$  has lattice periodicity

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$\varepsilon(\mathbf{k})$ : eigenvalue of  $H$

$$\psi_{\mathbf{k}n}(\mathbf{r}) = \exp(i\mathbf{k} \cdot \mathbf{r}) u_{\mathbf{k}n}(\mathbf{r}) \xrightarrow{\text{eigenvalue}} \varepsilon_n(\mathbf{k})$$

$n$ : extra index of eigenfunctions

$$\begin{aligned} \psi_{\mathbf{k}+\mathbf{K}n}(\mathbf{r}) &= \exp(i\mathbf{k} + \mathbf{K} \cdot \mathbf{r}) u_{\mathbf{k}+\mathbf{K}n}(\mathbf{r}) & \varepsilon_n(\mathbf{k} + \mathbf{K}) \\ &= \exp(i\mathbf{k} \cdot \mathbf{r}) \exp(i\mathbf{K} \cdot \mathbf{r}) u_{\mathbf{k}+\mathbf{K}n}(\mathbf{r}) \end{aligned}$$

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$$u_{\mathbf{k}n'}(\mathbf{r}) \longrightarrow \varepsilon_{n'}(\mathbf{k})$$

# Band structure

Plane-wave expansion

$$\begin{aligned}\psi_{\mathbf{k}}(\mathbf{r}) &= \exp(i\mathbf{k} \cdot \mathbf{r}) u_{\mathbf{k}}(\mathbf{r}) \\ &= \sum_{\mathbf{K}} c_{\mathbf{k}+\mathbf{K}} e^{i(\mathbf{k}+\mathbf{K}) \cdot \mathbf{r}}\end{aligned}$$

Periodic functions

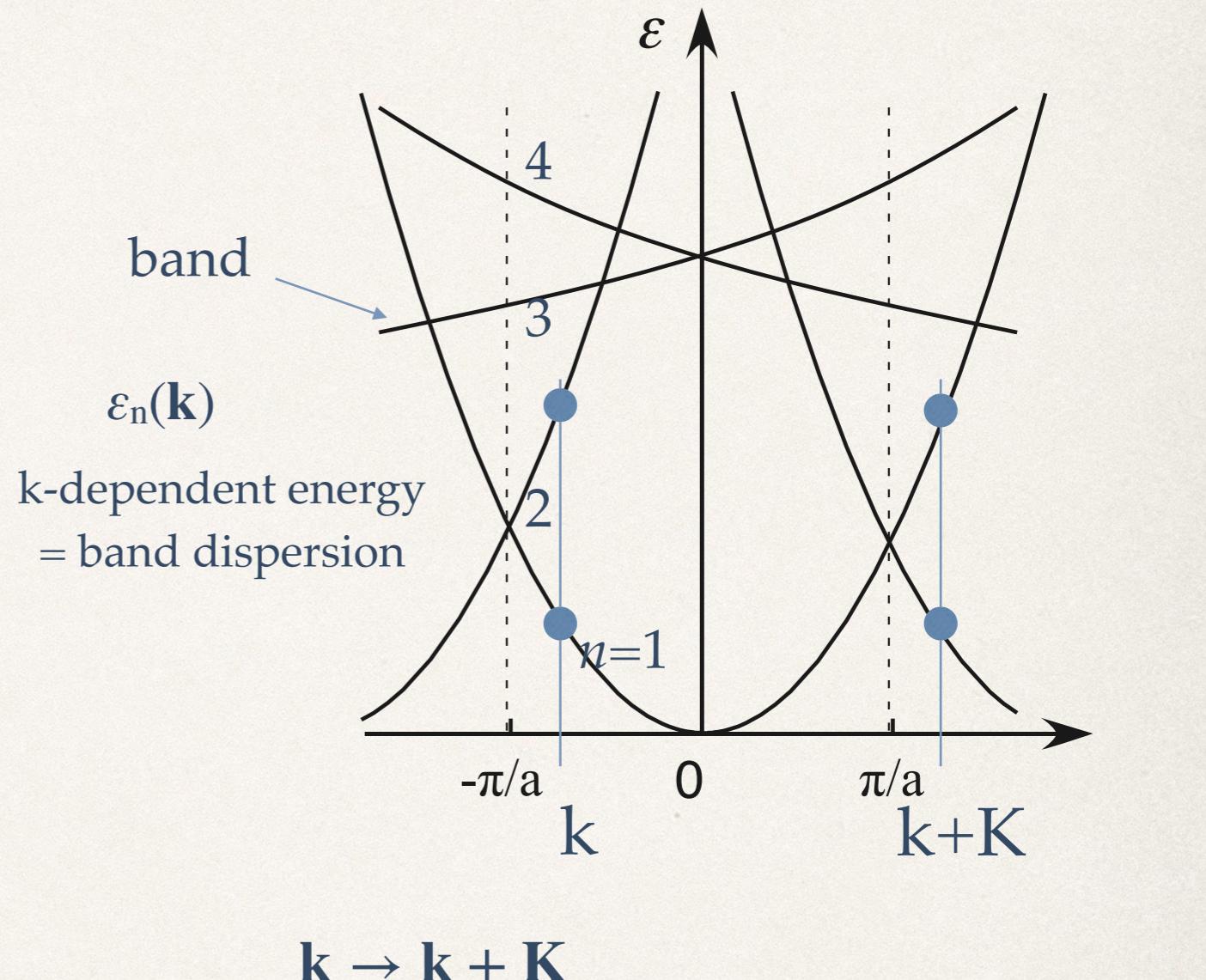
$$u_{\mathbf{k}}(\mathbf{r}) = \sum_{\mathbf{K}} c_{\mathbf{k}+\mathbf{K}} e^{i\mathbf{K} \cdot \mathbf{r}}$$

additional index

$\downarrow$   $n$ : band index

$$u_{\mathbf{k}n}(\mathbf{r}) = \sum_{\mathbf{K}} c_{\mathbf{K}n} e^{i\mathbf{K} \cdot \mathbf{r}}$$

$$\psi_{\mathbf{k}n}(\mathbf{r}) = \exp(i\mathbf{k} \cdot \mathbf{r}) u_{\mathbf{k}n}(\mathbf{r})$$



$$\begin{aligned}\psi_{\mathbf{k}+\mathbf{K}}(\mathbf{r}) &= \exp(i(\mathbf{k} + \mathbf{K}) \cdot \mathbf{r}) u_{\mathbf{k}+\mathbf{K}}(\mathbf{r}) \\ &= \exp(i\mathbf{k} \cdot \mathbf{r}) \exp(i\mathbf{K} \cdot \mathbf{r}) u_{\mathbf{k}+\mathbf{K}}(\mathbf{r})\end{aligned}$$

Even when  $k$  is restricted in the range  $-\pi/2 < k < \pi/2$ , additional band index  $n$  covers all the possible states.

periodic in  $\mathbf{R}$

# Free electrons

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$$\left\{ -\frac{\hbar^2}{2m} \nabla^2 + V(\mathbf{r}) \right\} \psi(\mathbf{r}) = \varepsilon \psi(\mathbf{r})$$

When  $V = 0$       ↓      free electrons

$$-\frac{\hbar^2}{2m} \nabla^2 \psi(\mathbf{r}) = \varepsilon \psi(\mathbf{r})$$

$$\varepsilon^0 = \frac{\hbar^2}{2m} \mathbf{k}^2$$

However,

Bloch theorem      →       $\varepsilon^0 = \frac{\hbar^2}{2m} (\mathbf{k} - \mathbf{K})^2$

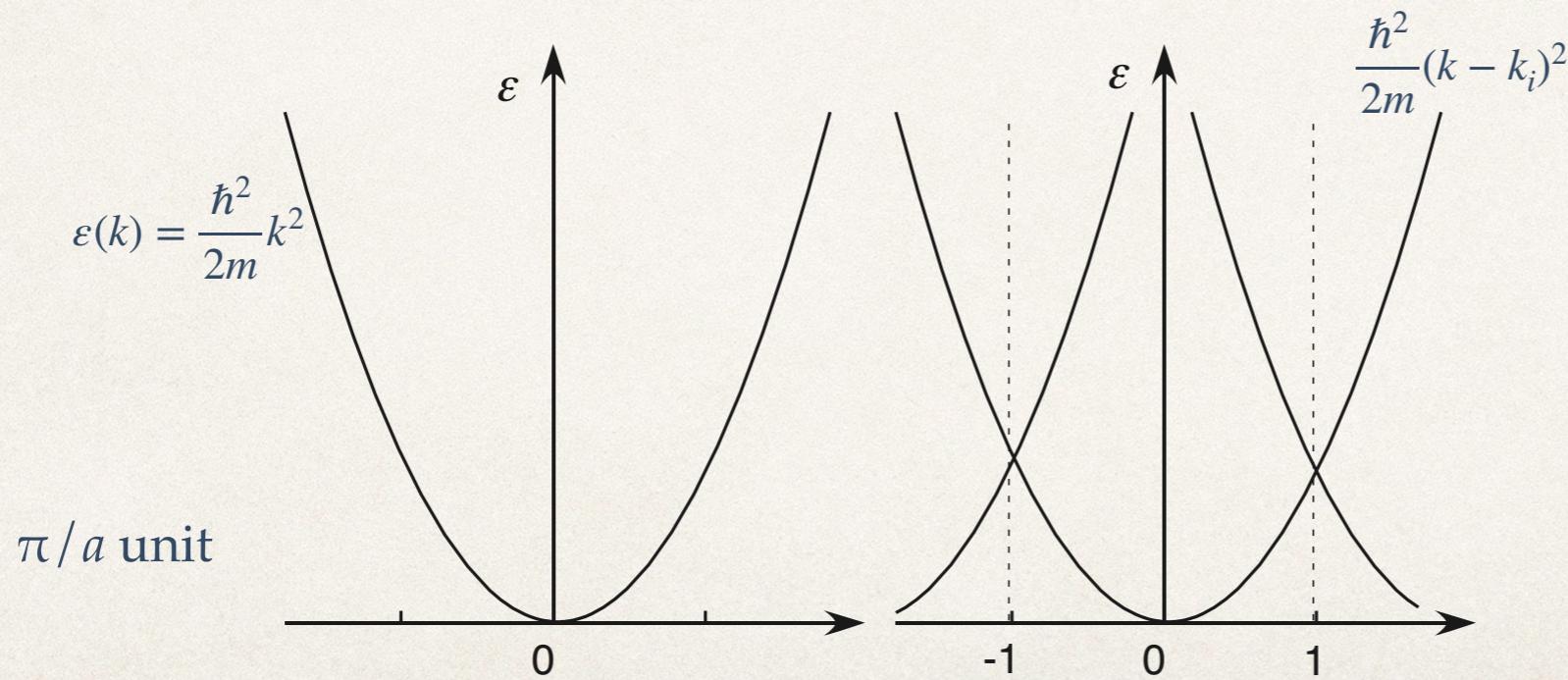
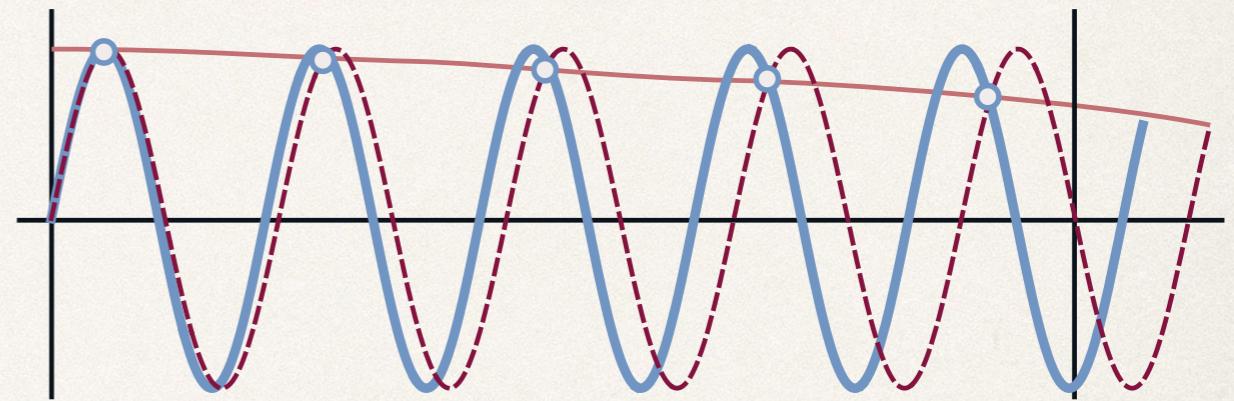
# Why does the band structure emerge even from free electrons?

Example)

$$e^{5.2xi} = \frac{e^{0.2xi}}{e^{ikx}} e^{5xi}$$

periodic function  
 $u(x + n) = u(x)$

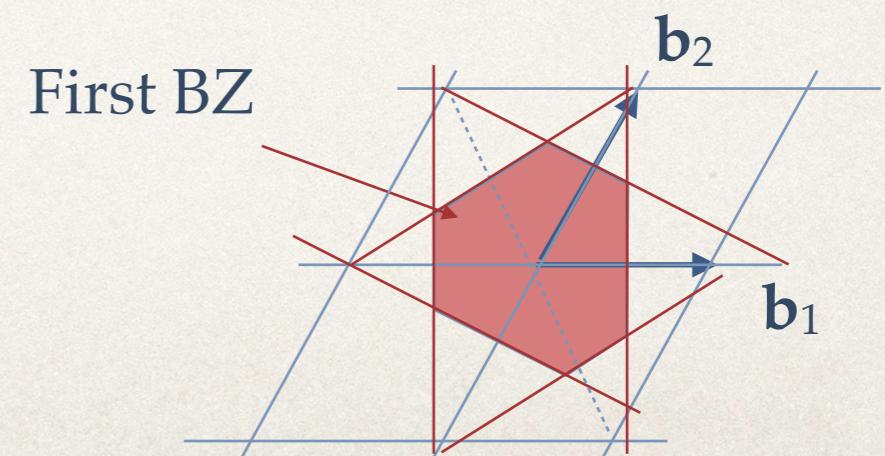
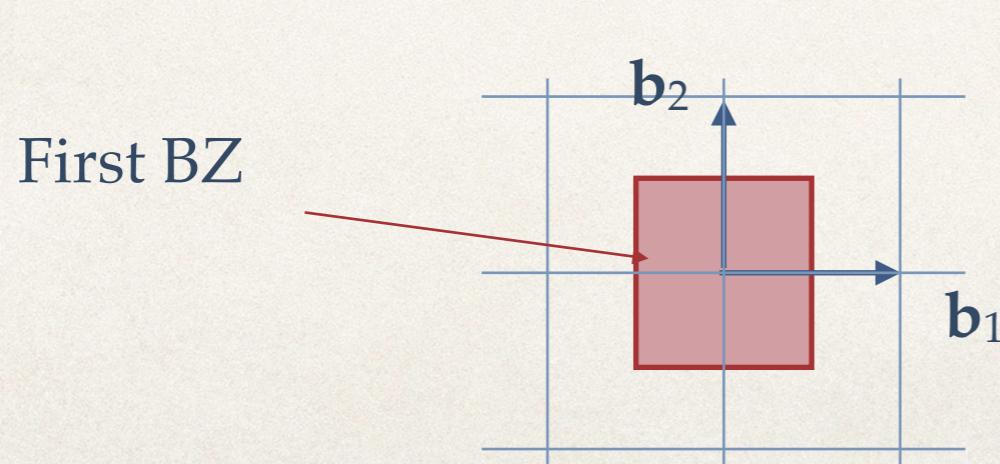
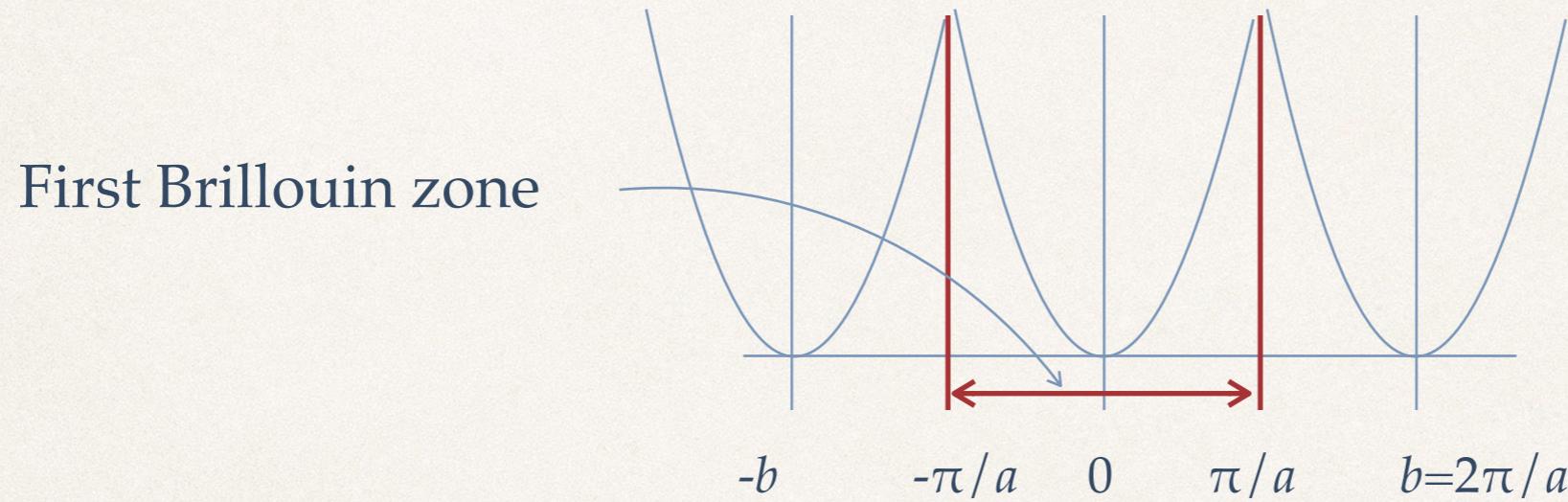
(envelope) + (periodic function)



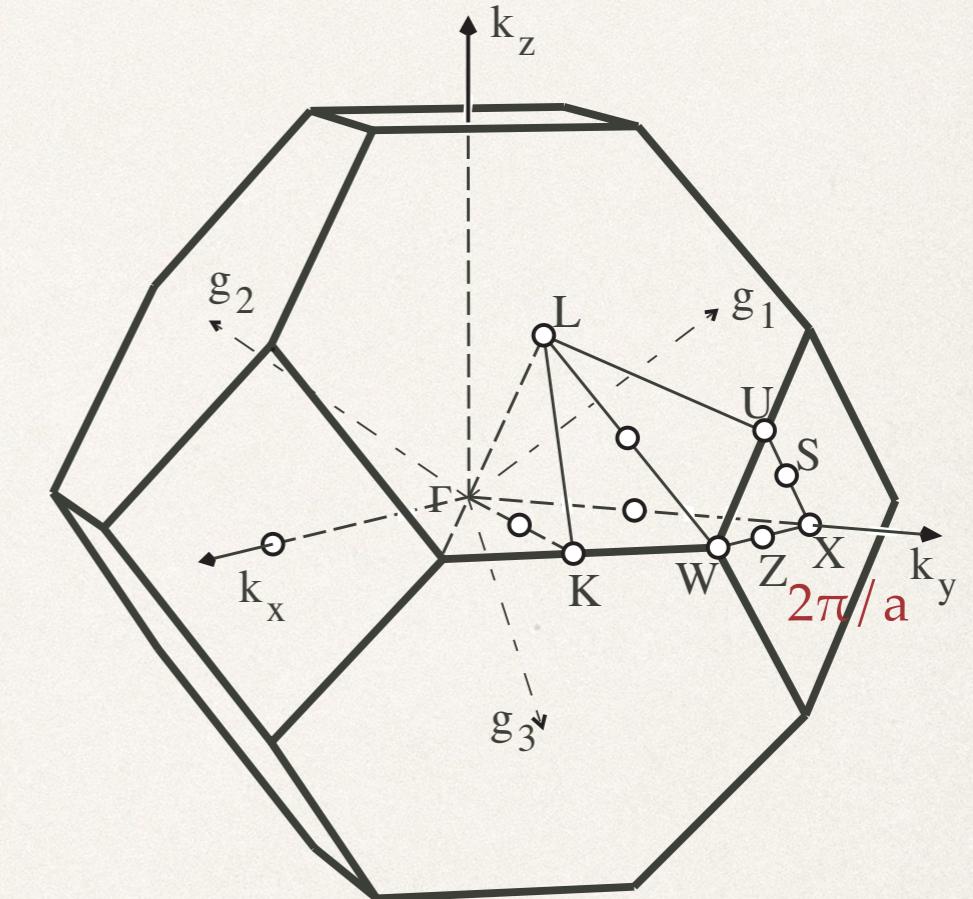
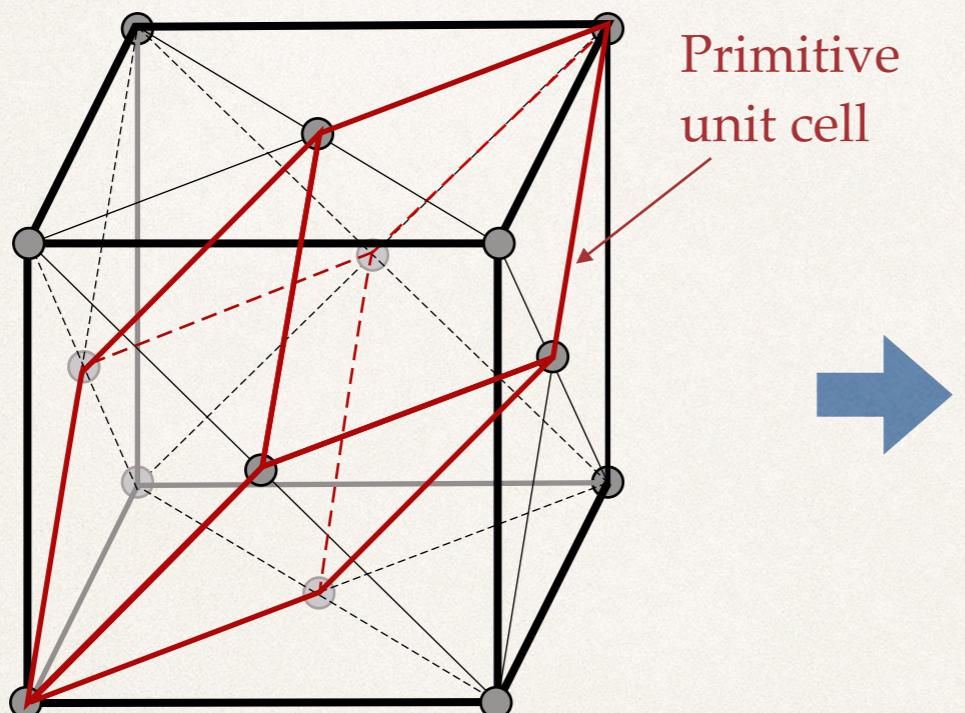
# Brillouin zone (BZ)

The minimum region in the  $\mathbf{k}$  space needed to indicate the periodicity.

Construction of a Brillouin zone (BZ)

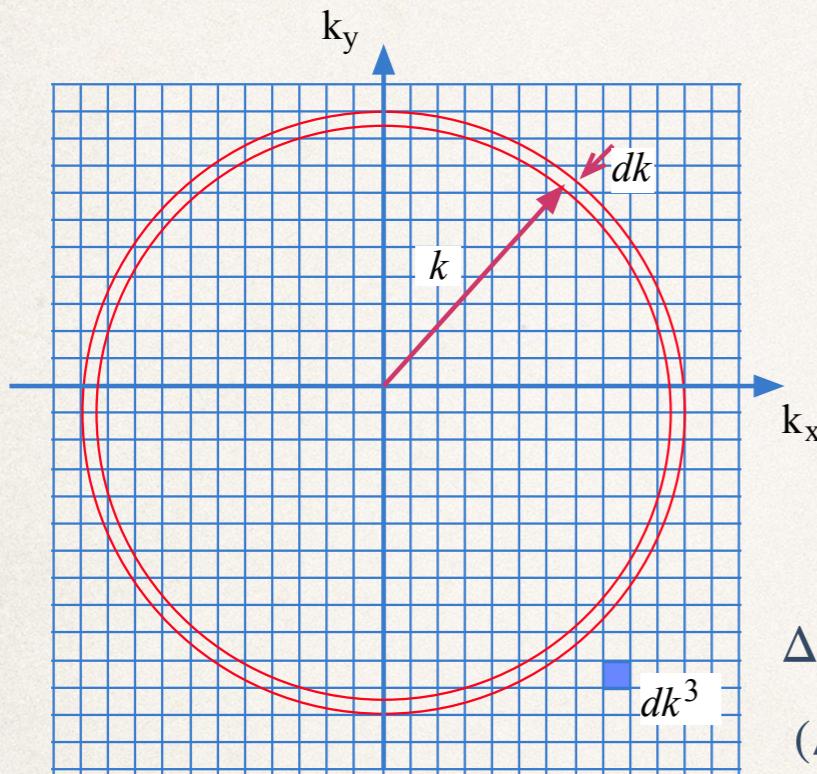


## Face-Centered-Cubic lattice



# Density-of-States (DOS)

Density of states in the energy space



spin states

$$\mathcal{N} = \frac{2}{N} \frac{1}{(\Delta k)^3} \frac{4\pi}{3} k^3$$

$$N = N_1 \bullet N_1 \bullet N_3$$

$$\varepsilon = \frac{\hbar^2}{2m} k^2$$

$$\Delta k = 2\pi \frac{1}{L}$$

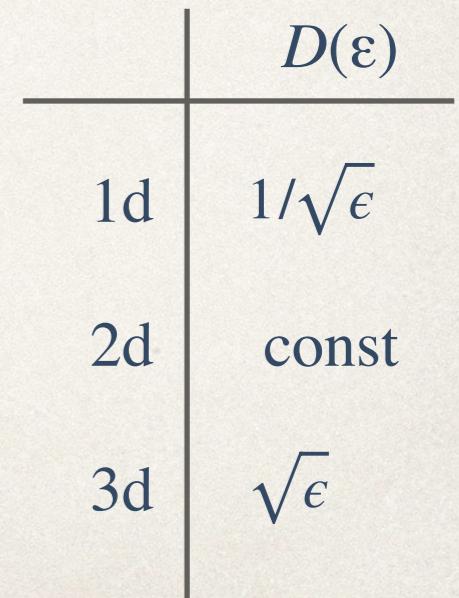
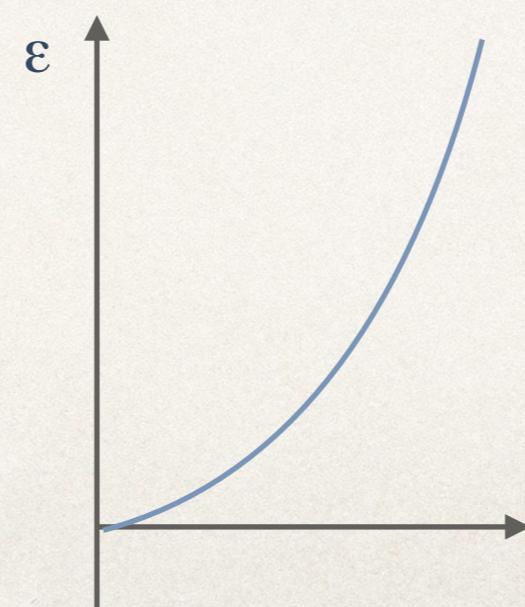
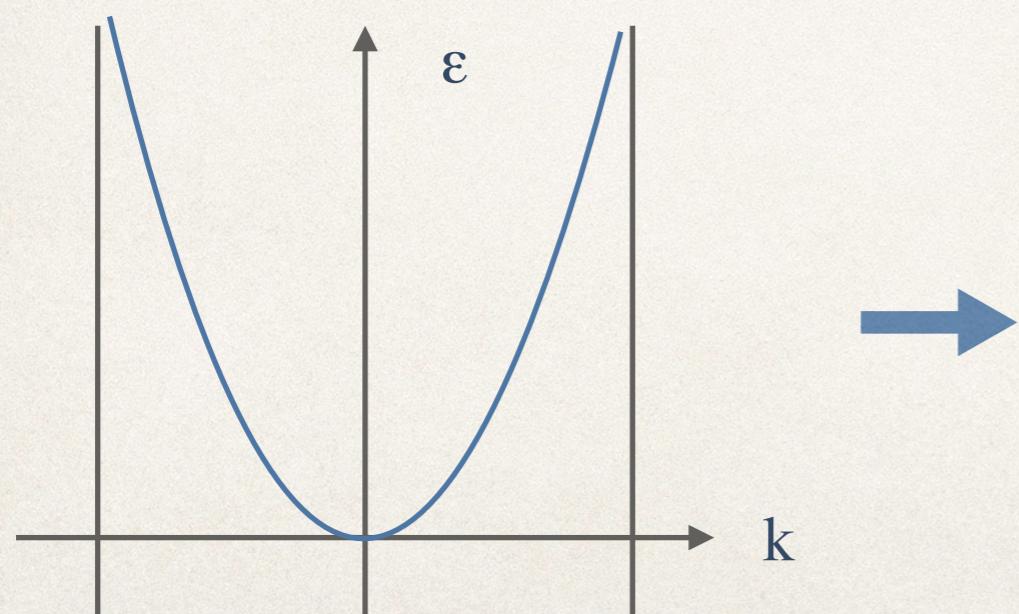
$$(\Delta k)^3 = \frac{(2\pi)^3}{V}$$

$$D(k) = \frac{d\mathcal{N}}{dk} = \frac{V}{N} \frac{1}{(2\pi)^3} 8\pi k^2$$

$$D(\varepsilon) = \frac{d\mathcal{N}}{dk} \frac{dk}{d\varepsilon} = \frac{V_c}{(2\pi)^3} 8\pi k^2 \frac{2m}{\hbar^2 k}$$

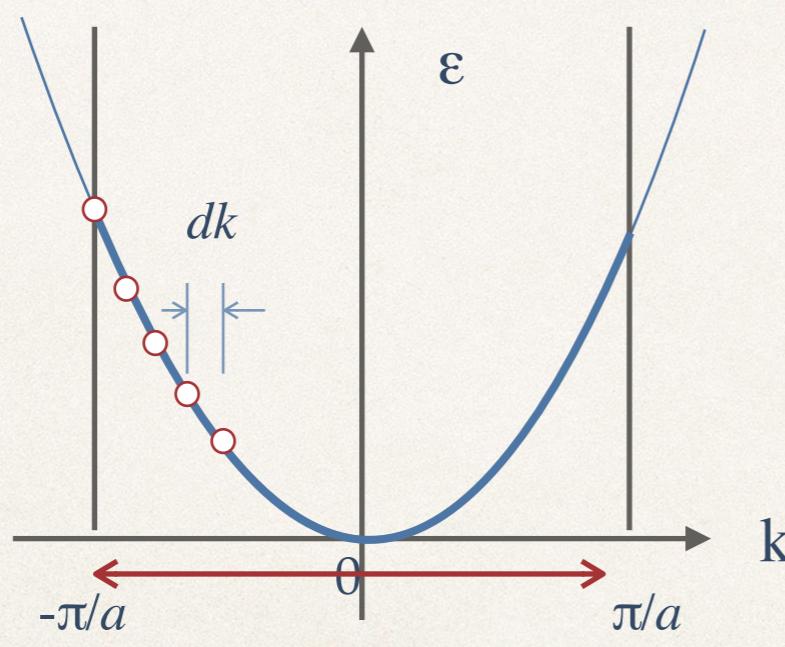
$$= V_c \frac{2\sqrt{2}m^{3/2}}{\pi^2 \hbar^3} \sqrt{\varepsilon}$$

$V_c$ : volume of unit cell



# Electron occupation

One band in a Brillouin zone contains exactly two electrons in a primitive unit cell.



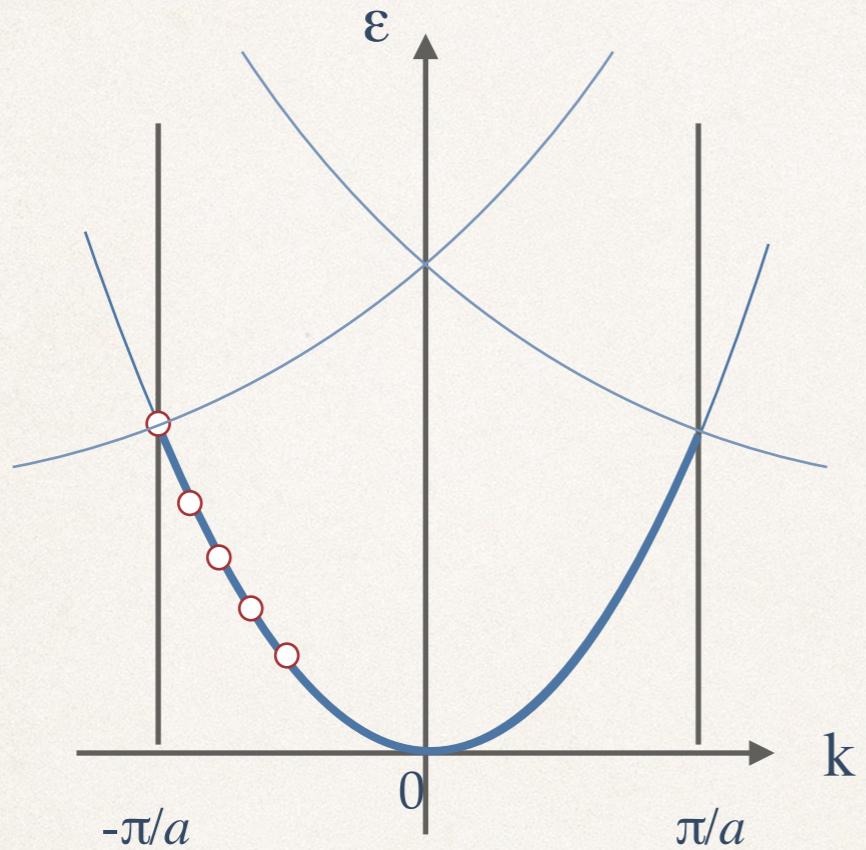
First Brillouin zone

$$\int_{BZ} D(k)dk = 2$$

the volume of BZ  
One BZ  
One unit cell  
two electrons in a cell

# Fermi energy

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$E_F$ : Fermi energy (level)

$$\int_0^{E_F} D(\epsilon) d\epsilon = N_{el}$$

Fermi surface

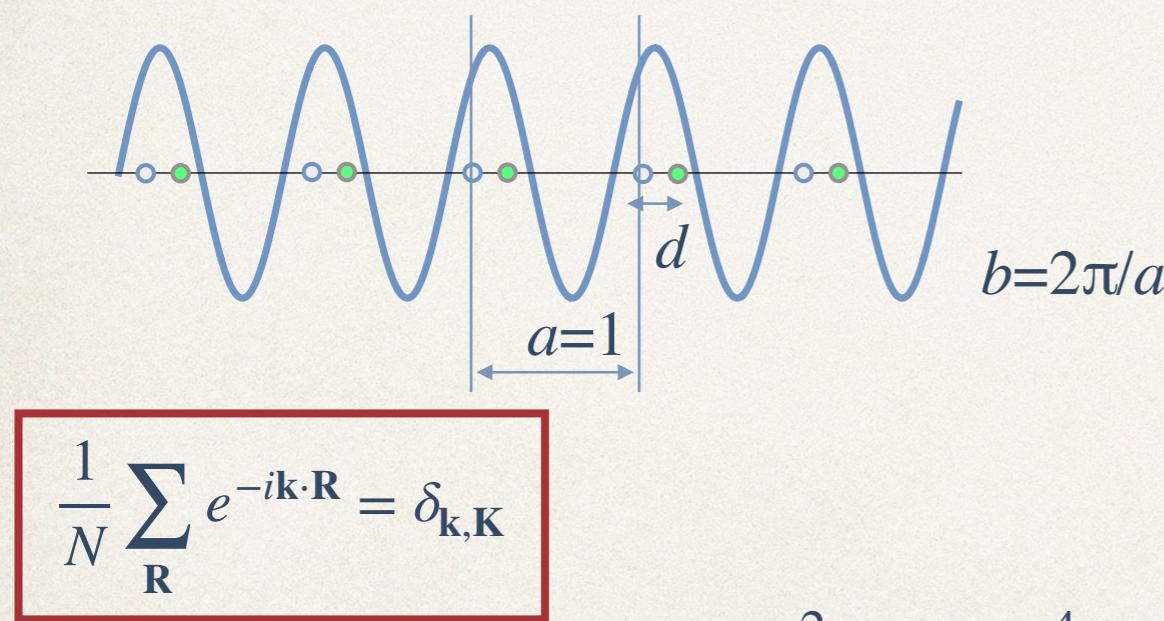
## 3.2 Band theory - 1

Nearly free electron approximation

# Nearly-free-electron approximation

# Potential

$$V(\mathbf{r}) = \sum_{\mathbf{K}} e^{i\mathbf{K}\cdot\mathbf{r}} V(\mathbf{K})$$



$$\frac{1}{N} \sum_{\mathbf{R}} e^{-i\mathbf{k}\cdot\mathbf{R}} = \delta_{\mathbf{k},\mathbf{K}}$$

$$\sum_{\mathbf{R}} e^{-i\mathbf{K}\cdot\mathbf{R}} = \frac{1}{1} + \frac{1}{1} + \frac{1}{1} + \dots = N$$

## atom potential

$$V(\mathbf{r}) = \sum_{\mathbf{R}kj} U_k(\mathbf{r} - \mathbf{R} - \mathbf{d}_{kj})$$

Atom potential of

Atom potential of  
 $j$ -th atom of the same chemical species  $\kappa$

$$\begin{aligned}
&= \sum_{\mathbf{R}\kappa j} \frac{1}{\Omega} \int d\mathbf{r} e^{-i\mathbf{K}\cdot\mathbf{r}} U_\kappa(\mathbf{r} - \mathbf{R} - \mathbf{d}_{\kappa j}) \\
&= \sum_{\mathbf{R}\kappa j} \frac{1}{\Omega} \int d\mathbf{r}' e^{-i\mathbf{K}\cdot(\mathbf{r}' + \mathbf{R} + \mathbf{d}_{\kappa j})} U_\kappa(\mathbf{r}') \\
&= \frac{1}{\Omega} \sum_\kappa \sum_{\mathbf{R}} e^{-i\mathbf{K}\cdot\mathbf{R}} \sum_j e^{-i\mathbf{K}\cdot\mathbf{d}_{\kappa j}} \int d\mathbf{r} e^{-i\mathbf{K}\cdot\mathbf{r}} U_\kappa(\mathbf{r}) \\
&= \sum_\kappa \left( \sum_j e^{-i\mathbf{K}\cdot\mathbf{d}_{\kappa j}} \sum_{\mathbf{R}} e^{-i\mathbf{K}\cdot\mathbf{R}} \right) U_\kappa(\mathbf{K})
\end{aligned}$$

$$S_K(\mathbf{K})$$

## form factor

## structural factor

# Schrödinger equation

$$\psi(\mathbf{r}) = \sum_{\mathbf{q}} c_{\mathbf{q}} e^{i\mathbf{q} \cdot \mathbf{r}} \quad \leftarrow \quad e^{i\mathbf{k} \cdot \mathbf{r}} \sum_{\mathbf{K}} c_{\mathbf{k}+\mathbf{K}} e^{i\mathbf{K} \cdot \mathbf{r}}$$

$\mathbf{q} = \mathbf{k} - \mathbf{K}$

$$\left\{ -\frac{\hbar^2}{2m} \nabla^2 + V(\mathbf{r}) \right\} \psi(\mathbf{r}) = \varepsilon \psi(\mathbf{r})$$

$$\sum_{\mathbf{q}} e^{i\mathbf{q} \cdot \mathbf{r}} \left\{ \left( \frac{\hbar^2}{2m} q^2 - \varepsilon \right) c_{\mathbf{q}} + \sum_{\mathbf{K}'} V(\mathbf{K}') c_{\mathbf{q}-\mathbf{K}'} \right\} = 0$$

matrix form

unit:  $\frac{\hbar^2}{2m} = 1$

$$\begin{vmatrix} \mathbf{k}^2 - \varepsilon & V(\mathbf{K}_1) & V(\mathbf{K}_2) & \dots \\ V(\mathbf{K}_1) & (\mathbf{k} - \mathbf{K}_1)^2 - \varepsilon & V(\mathbf{K}_2 - \mathbf{K}_1) & \dots \\ V(\mathbf{K}_2) & V(\mathbf{K}_2 - \mathbf{K}_1) & (\mathbf{k} - \mathbf{K}_2)^2 - \varepsilon & \dots \\ \dots & & & \\ & & & = 0 \end{vmatrix}$$

$$\left( \frac{\hbar^2}{2m} (\mathbf{k} - \mathbf{K})^2 - \varepsilon \right) c_{\mathbf{k}-\mathbf{K}} + \sum_{\mathbf{K}'} V(\mathbf{K}' - \mathbf{K}) c_{\mathbf{k}-\mathbf{K}'} = 0$$

When  $V = 0$

$$\longrightarrow \quad \varepsilon^0 = \frac{\hbar^2}{2m} (\mathbf{k} - \mathbf{K})^2$$

free electrons

# Role of crystal potentials

At a zone boundary

$$\mathbf{k} = \frac{1}{2}\mathbf{K}$$

$$\begin{vmatrix} (\mathbf{K}/2)^2 - \varepsilon & V(\mathbf{K}) \\ V(\mathbf{K}) & (\mathbf{K}/2)^2 - \varepsilon \end{vmatrix} = 0$$

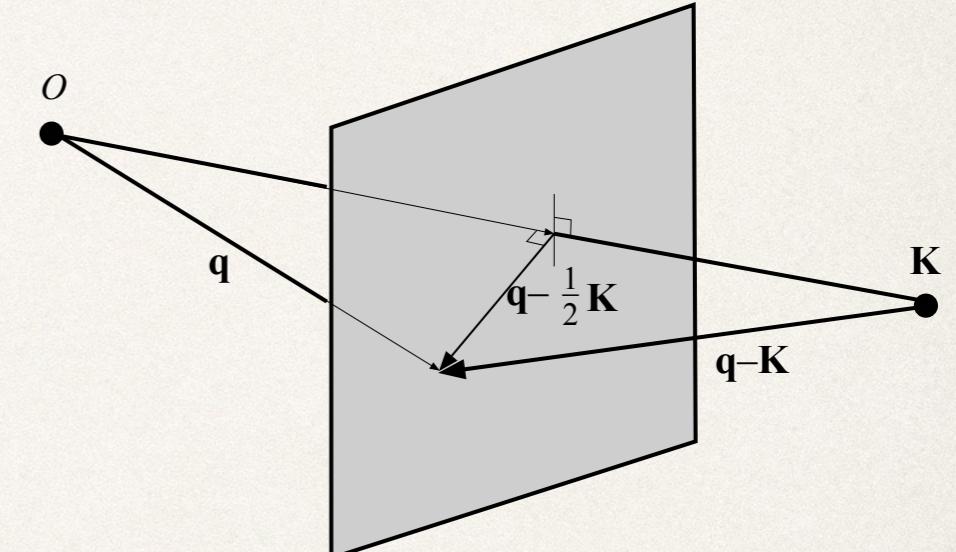
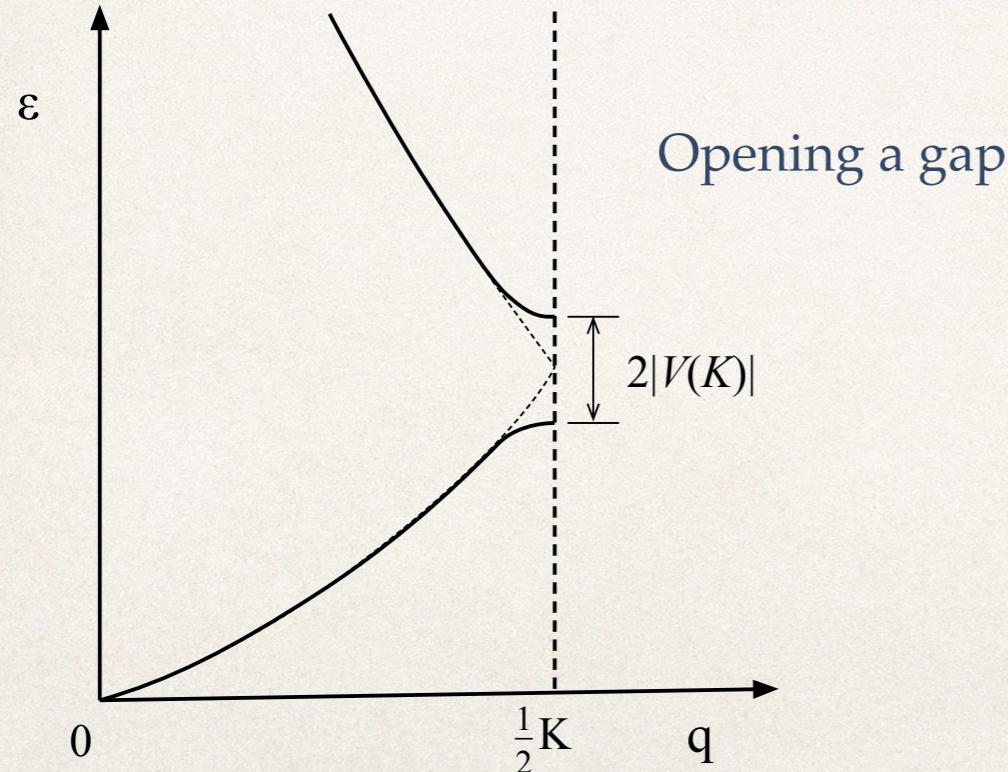
Degenerate case

$$\mathbf{q} = \mathbf{k} - \mathbf{K}$$

Bragg reflection

$$|\mathbf{q}| = |\mathbf{q} - \mathbf{K}|$$

$$\varepsilon = \varepsilon_{\mathbf{K}/2}^0 \pm |V(\mathbf{K})|$$



When Bragg reflection occurs, an energy gap is opened at that point  $\mathbf{q}$ .

# Bragg reflection

われる。ここでは弾性散乱を考えていて、X線の波長は反射のときに変化しない散乱（弾性波の励起を伴う散乱）については章末において述べる。

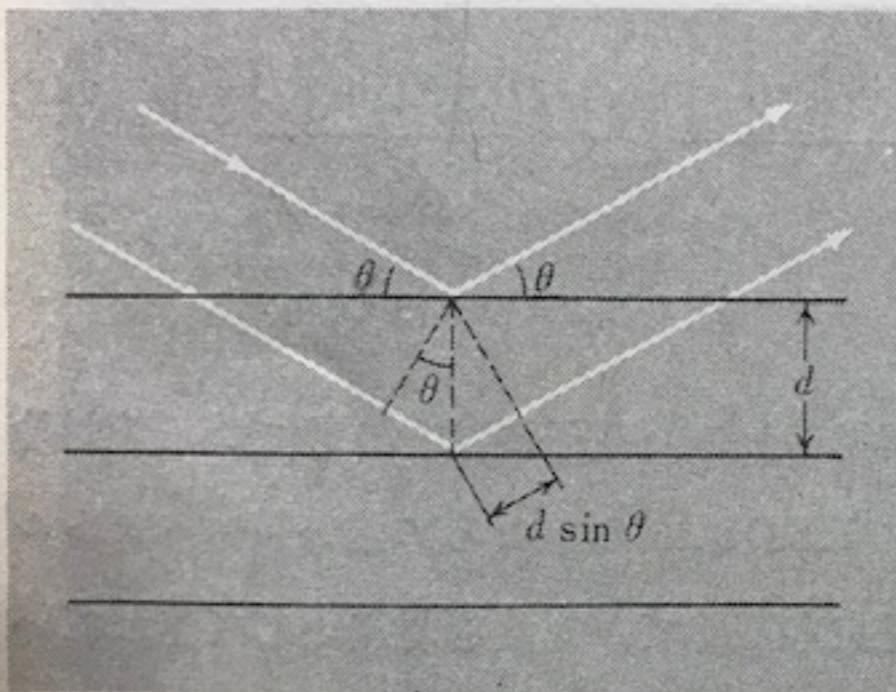


図 2・3 ブラッグの式  $2d \sin \theta = n\lambda$  の導出。ここに  $d$  は平行な原子面の面間隔。 $2n\pi$  は、つぎつぎの面からの反射波間の位相差である。反射面は試料の外形上の表面とは関係がない。

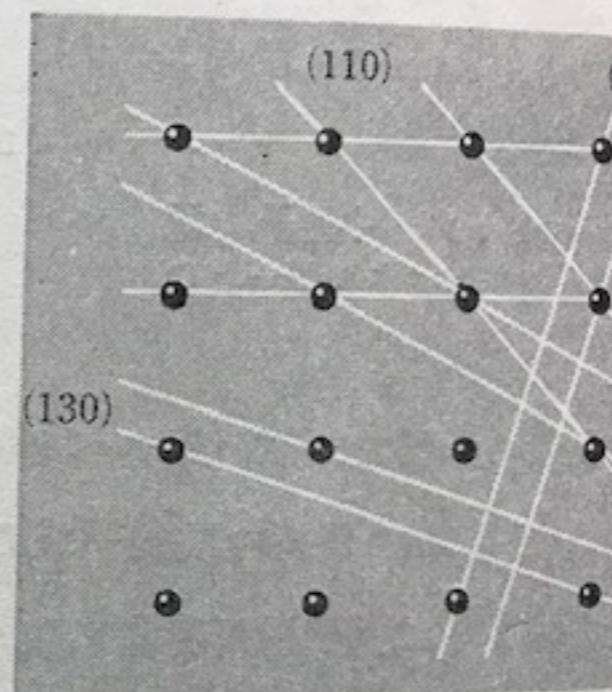


図 2・4 単純立方結晶格子での反射面には指数を付けて区別している。1組の平行な2面を示す。平行な面間隔は指数が増すと減少する。それらの反射を起こすには短い波長の波がある。

$$|\mathbf{q}| = |\mathbf{q} - \mathbf{K}|$$

$$|\mathbf{q}|^2 = |\mathbf{q} - \mathbf{K}|^2$$

$$K^2 = 2Kq \cos \theta$$

$$K = 2q \cos \theta$$

$$\frac{\lambda}{d} = 2 \cos \theta$$

# Correspondence to X-ray diffraction

## Structural factor

$$S(hkl) = \sum_j f_j \exp\left[-2\pi i(x_j h + y_j k + z_j l)\right] \quad (hkl) \text{ Muller index}$$

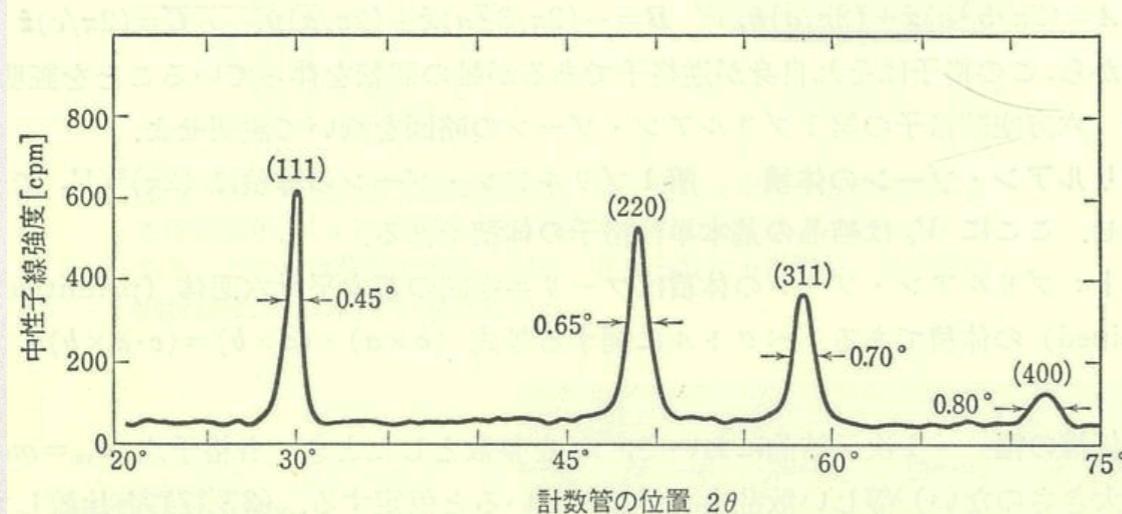
$$= \sum_{\kappa} f_{\kappa} \sum_j \exp\left[-2\pi i(x_j h + y_j k + z_j l)\right] \quad \kappa: \text{chemical species}$$

$$\overline{S_{\kappa}(hkl)} \quad \text{of symmetry equivalent}$$

$S_{\kappa}(hkl)$       FCC       $1 + \exp[i\pi(h+k)] + \exp[i\pi(k+l)] + \exp[i\pi(l+h)]$

vanishes when both even and odd numbers are present

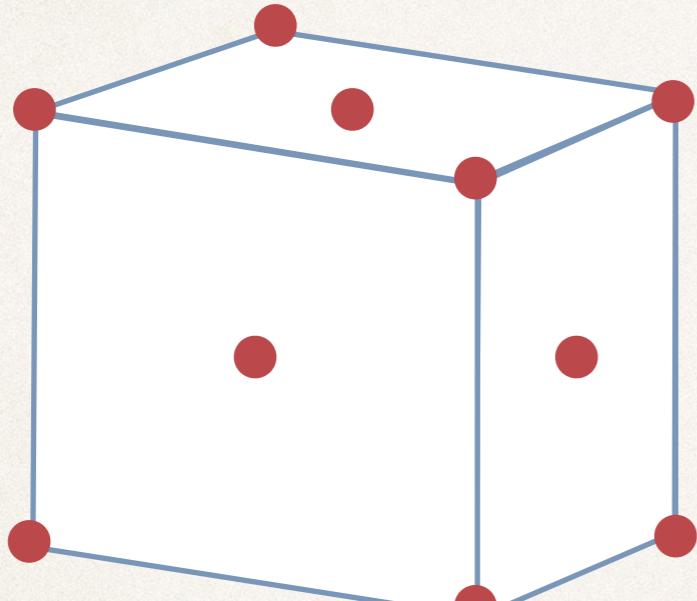
Diamond  $(1 + \exp[i\pi(h+k)] + \exp[i\pi(k+l)] + \exp[i\pi(l+h)]) \left(1 + \exp\left[i\frac{\pi}{2}(h+k+l)\right]\right)$



Extinction rule for FCC  
+  
 $hkl$ : even for all and  
 $h+k+l \neq 4n$

# FCC

---



$$(0, 0, 0)$$

$$\left(\frac{1}{2}, \frac{1}{2}, 0\right)$$

$$\left(\frac{1}{2}, 0, \frac{1}{2}\right)$$

$$\left(0, \frac{1}{2}, \frac{1}{2}\right)$$

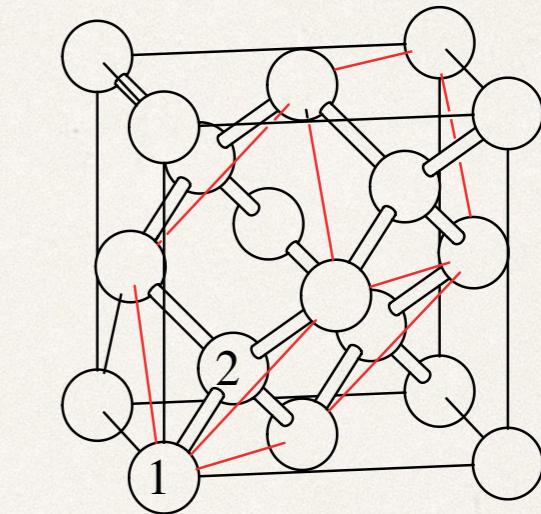
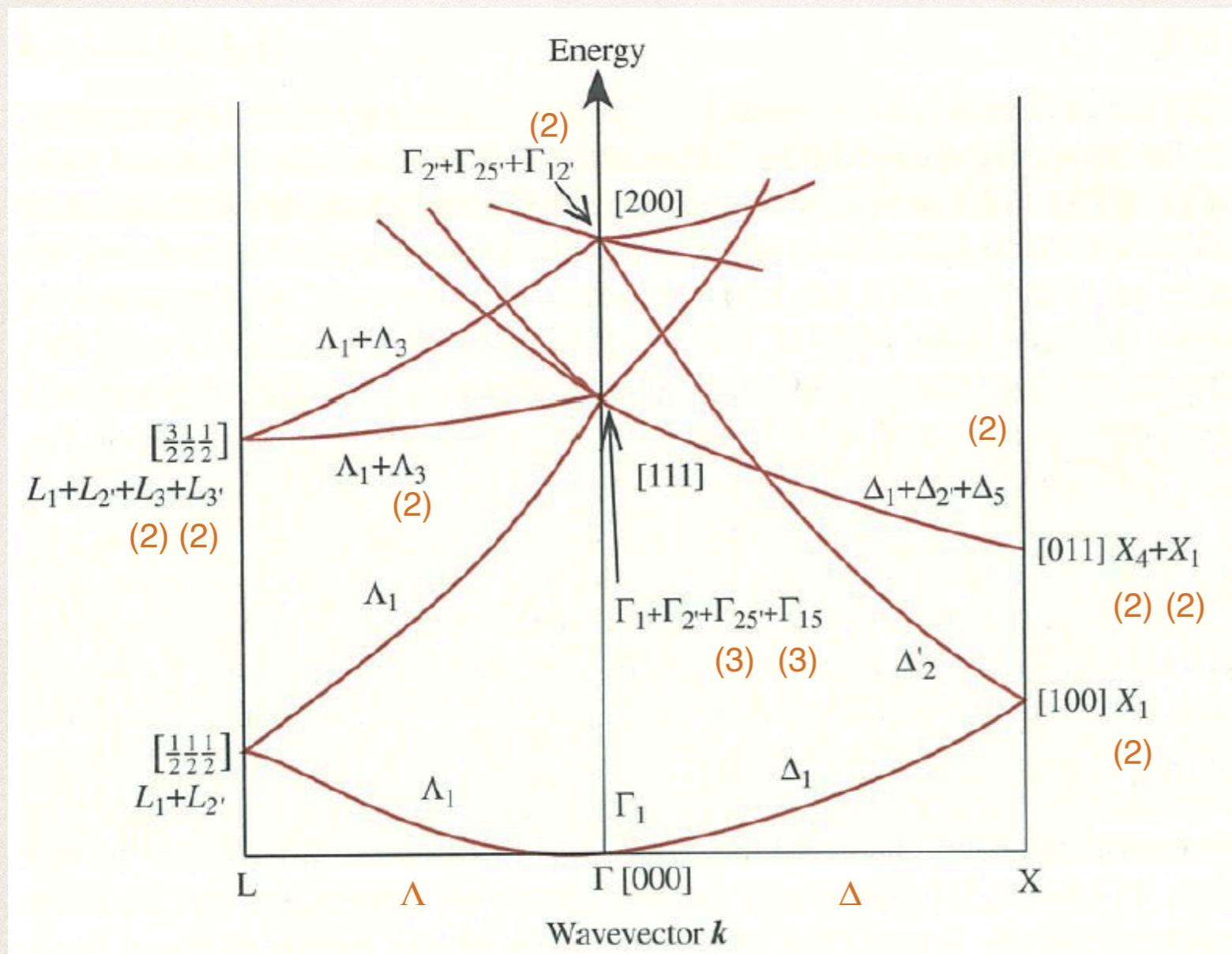
$$\begin{aligned}
 S(\mathbf{K}) &= \sum_{\mathbf{R}} e^{-i\mathbf{K}\cdot\mathbf{R}} \\
 &= \sum_{\mathbf{R}} e^{-i\mathbf{K}\cdot\mathbf{R}} \left( 1 + e^{-i\frac{1}{2}\mathbf{K}\cdot(110)} + e^{-i\frac{1}{2}\mathbf{K}\cdot(101)} + e^{-i\frac{1}{2}\mathbf{K}\cdot(011)} \right) \\
 &= \sum_{\mathbf{R}} e^{-i\mathbf{K}\cdot\mathbf{R}} \left( 1 + e^{-i\frac{1}{2}(h+k)} + e^{-i\frac{1}{2}(h+l)} + e^{-i\frac{1}{2}(k+l)} \right)
 \end{aligned}$$

# Examples of free-electron bands

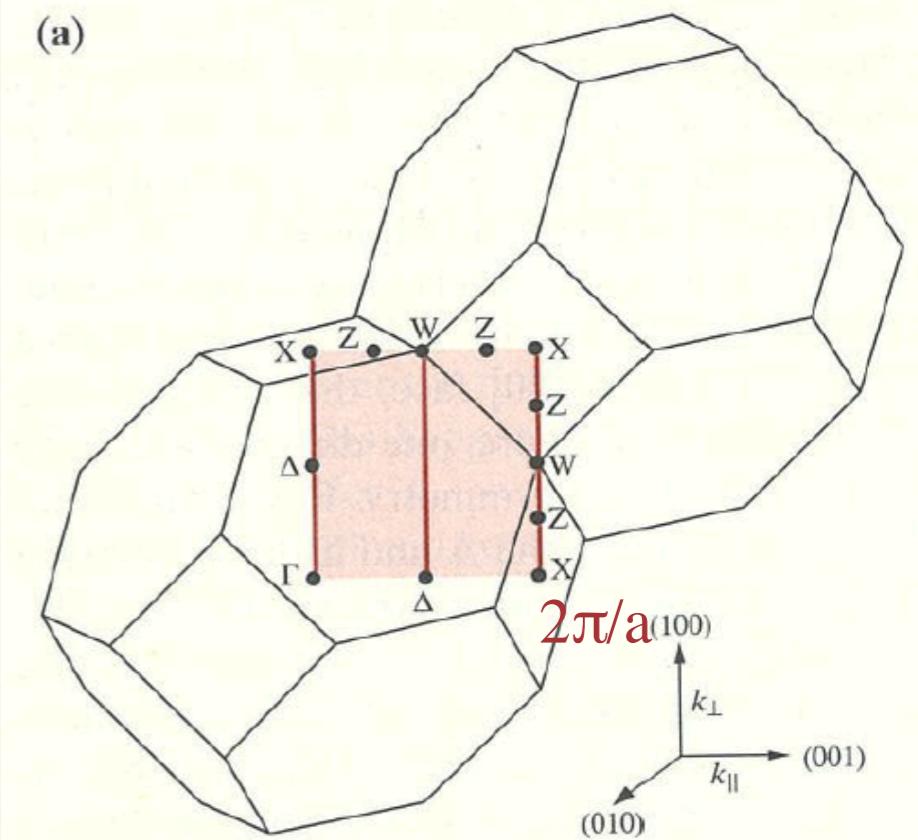
## Diamond structure

Si

2 at/cell  
8 el/cell

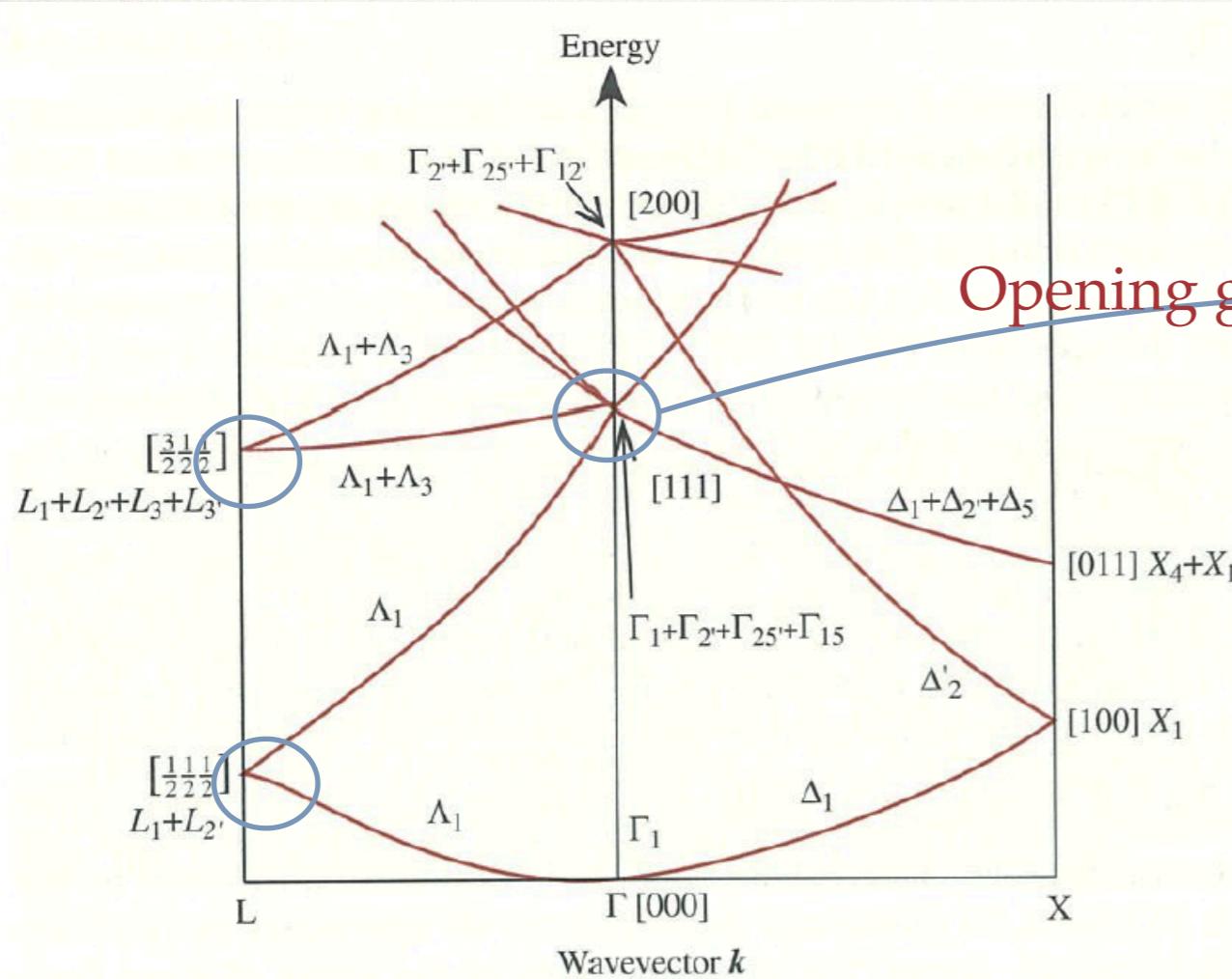


(a)



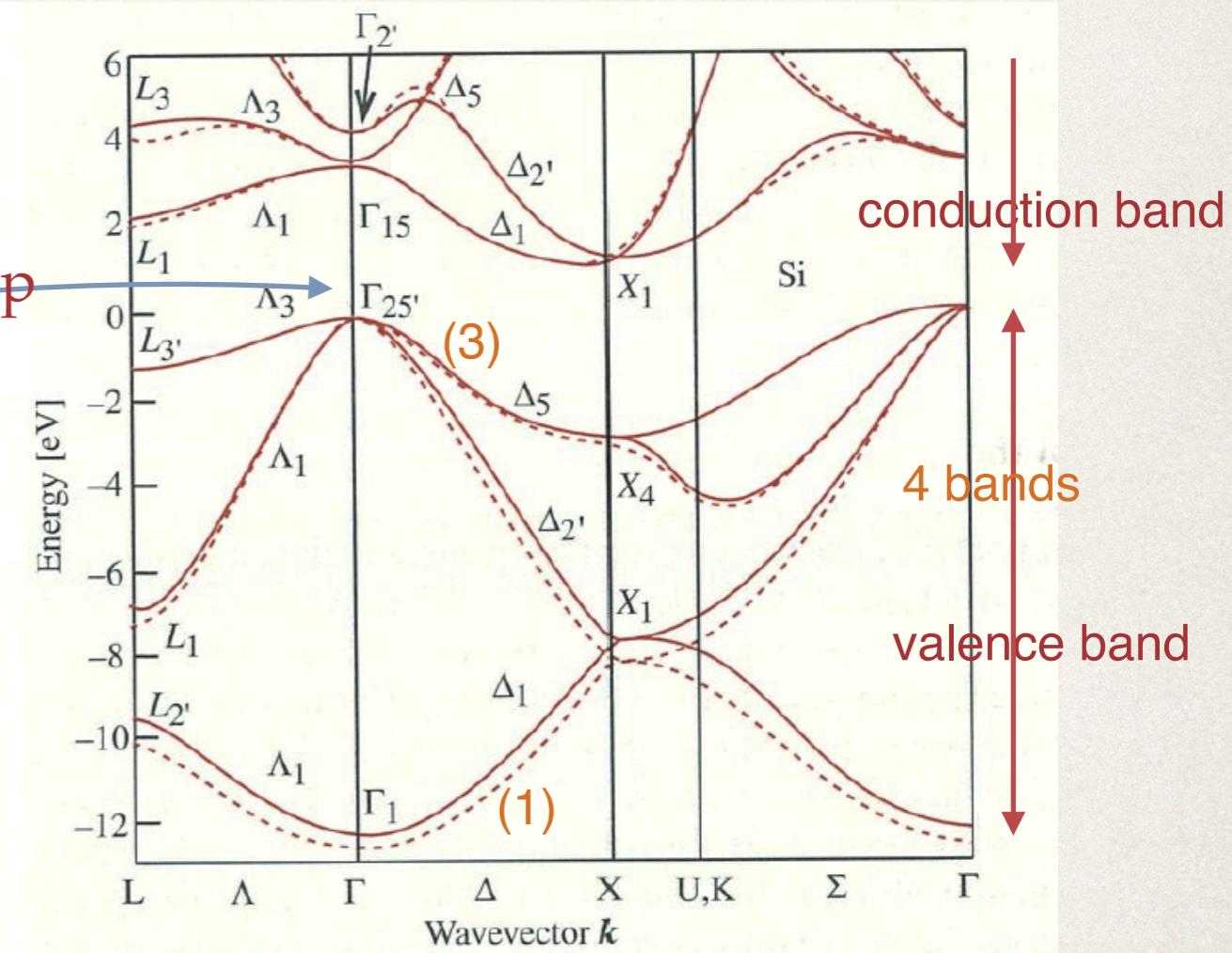
# Comparison of free-electron band with the real band

Bragg reflection and band gap

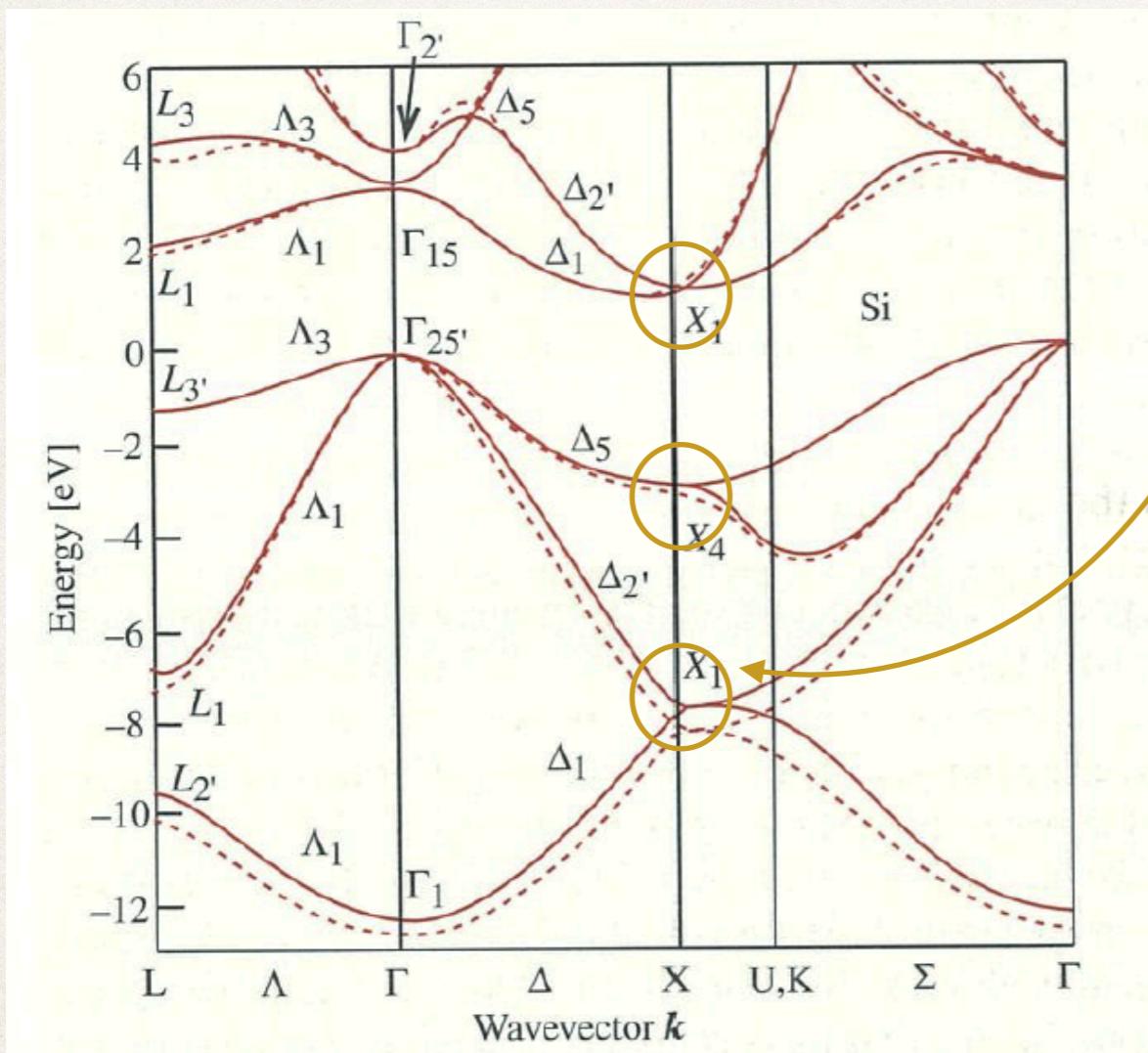


Si crystal

$N_{\text{el}} = 8$



# Symmetry consequence



Why not splitting?

at  $\mathbf{k} = X$

$$\frac{2\pi}{a}(1,0,0)$$

Bragg reflection would be expected by

$$\mathbf{K} = (2, 0, 0)$$

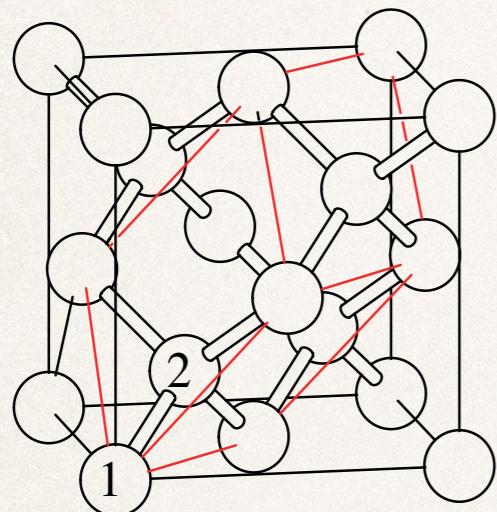
But for the diamond structure

$$V(2, 0, 0) = 0$$

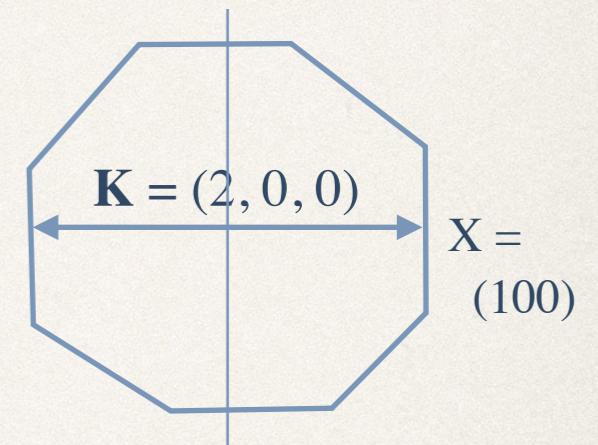
No reflection!

# Exercise 1

For the diamond structure, show the crystal potential  $V(K) = 0$  at  $K=(2, 0, 0)$ .



Hint: show  $S(K) = 0$



2 atom/primitive unit cell

$$1: \quad (0, 0, 0)$$

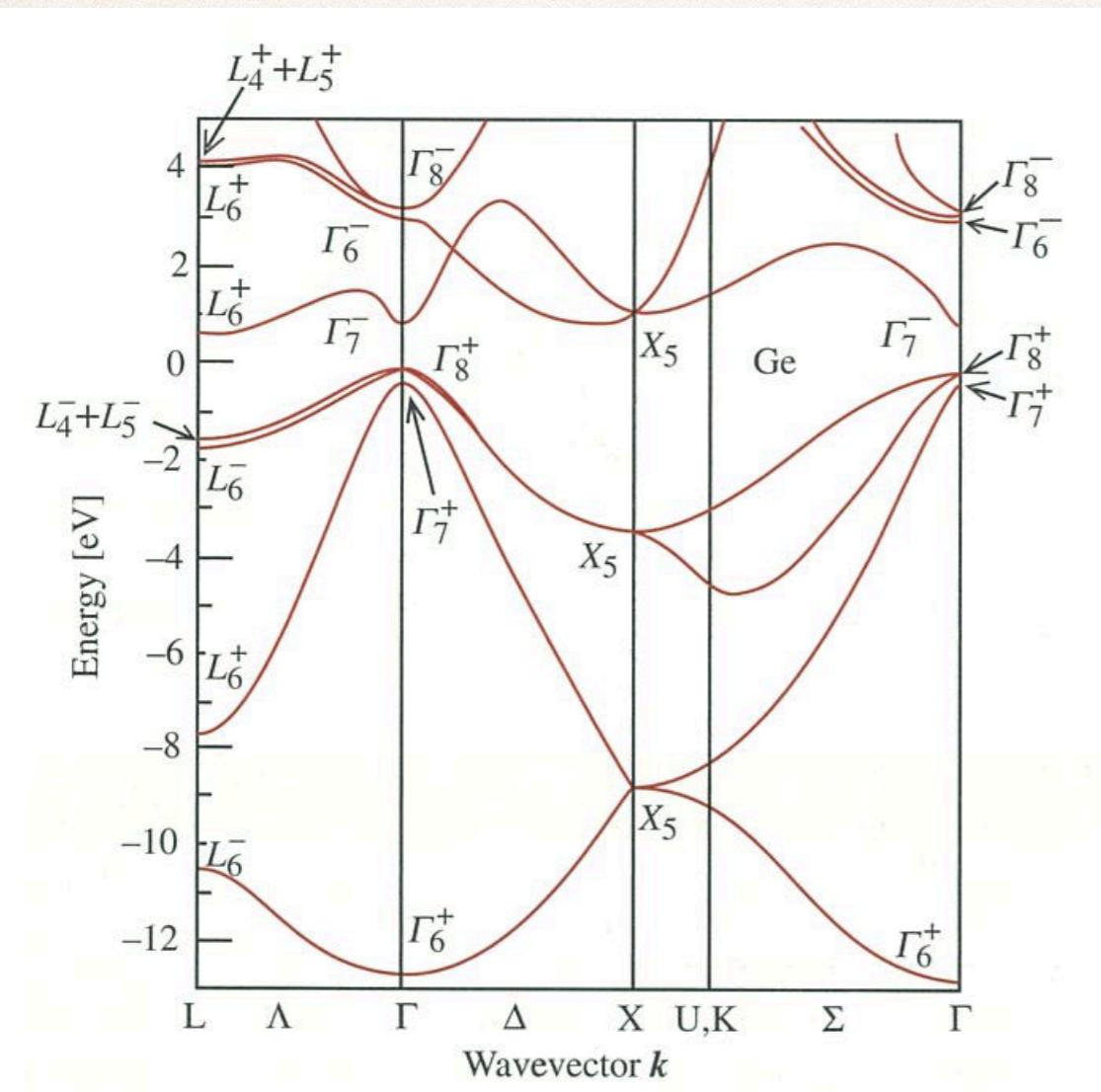
$$2: \quad \frac{1}{4}(1, 1, 1)$$

$$S(\mathbf{K}) = \sum_{\mathbf{R}} e^{-i\mathbf{K}\cdot\mathbf{R}} = \sum_{\mathbf{R}} \sum_j e^{-i\mathbf{K}\cdot\mathbf{d}_j}$$

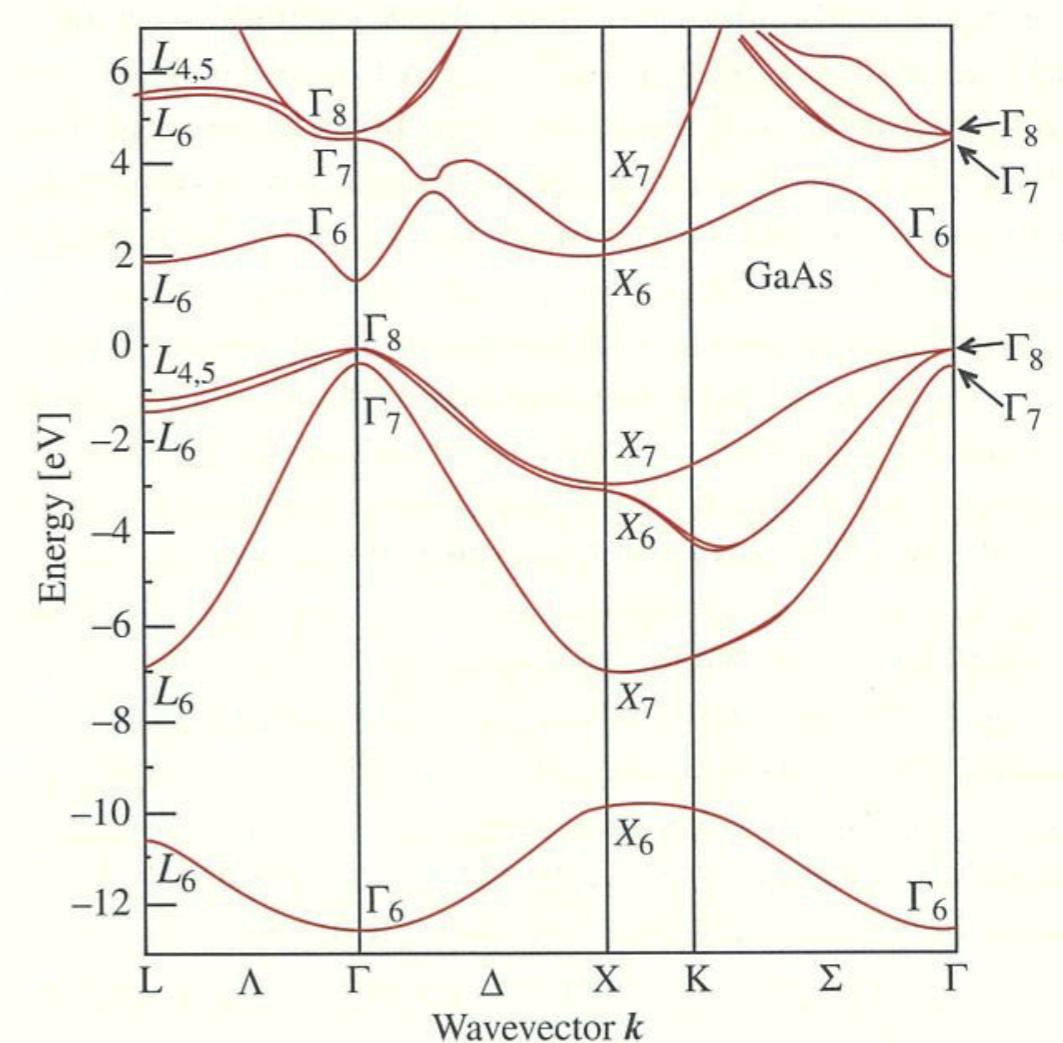
$j$	1	2	$S(\mathbf{K})$
$\mathbf{K} \cdot \mathbf{d}_j$	0	$\pi$	
$e^{-i\mathbf{K}\cdot\mathbf{d}_j}$	1	-1	0

# Energy band with spin freedom

Ge



GaAs



## 3.3 Band theory - 2

Tight-binding approximation

# Atomic Orbitals

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Atomic orbitals

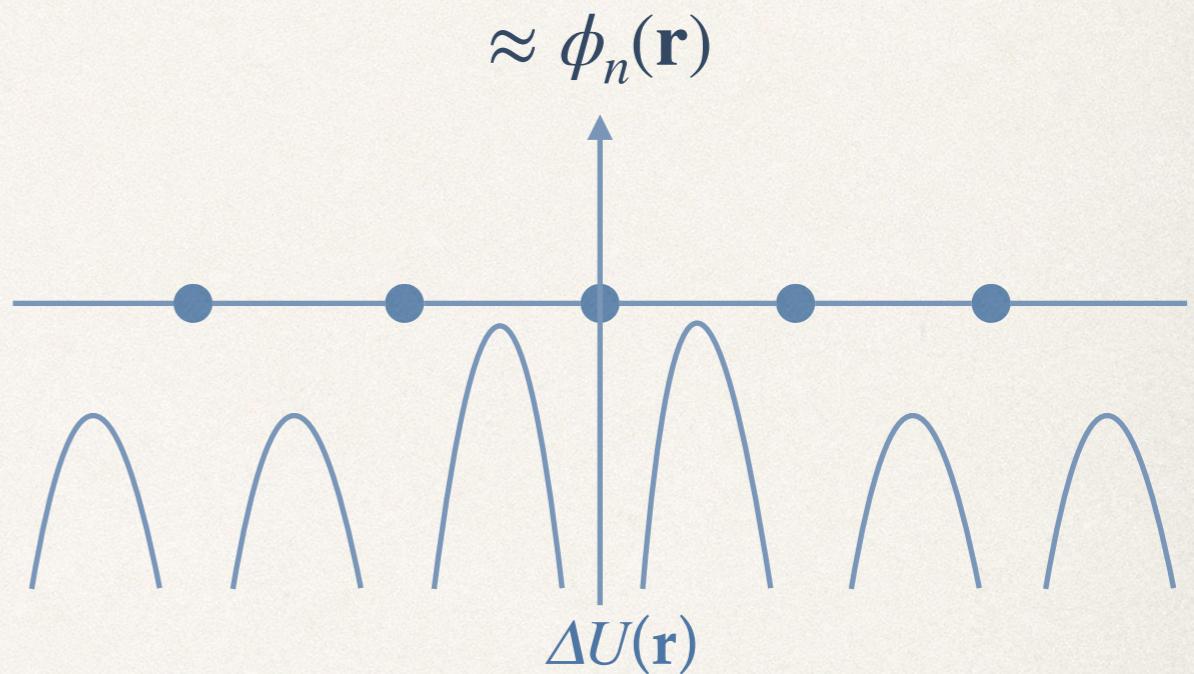
$$H_{\text{at}}\phi_n(\mathbf{r}) = E_n\phi_n(\mathbf{r})$$

$$H_{\text{at}} = -\frac{\hbar^2}{2m}\nabla^2 + U_{\text{at}}(\mathbf{r})$$

Crystal potential

$$V(\mathbf{r}) = U_{\text{at}}(\mathbf{r}) + \Delta U(\mathbf{r})$$

$$H = H_{\text{at}} + \Delta U(\mathbf{r})$$



# Linear-Combination-Atomic-Orbitals

---

$$\varphi_n(\mathbf{r}) = \sum_{\mathbf{R}} e^{i\mathbf{k}\cdot\mathbf{R}} \phi_n(\mathbf{r} - \mathbf{R}) \quad (\text{LCAO})$$

===== atomic orbitals

Bloch condition

$$\begin{aligned}
 T(\mathbf{R}')\varphi_n(\mathbf{r}) &= \sum_{\mathbf{R}} e^{i\mathbf{k}\cdot\mathbf{R}} \phi_n(\mathbf{r} - (\mathbf{R} - \mathbf{R}')) \\
 &= \sum_{\mathbf{R}''} e^{i\mathbf{k}\cdot(\mathbf{R}'' + \mathbf{R}')} \phi_n(\mathbf{r} - \mathbf{R}'') \\
 &= e^{i\mathbf{k}\cdot\mathbf{R}'} \sum_{\mathbf{R}''} e^{i\mathbf{k}\cdot\mathbf{R}''} \phi_n(\mathbf{r} - \mathbf{R}'') = e^{i\mathbf{k}\cdot\mathbf{R}'} \varphi_n(\mathbf{r})
 \end{aligned}
 \quad \mathbf{R} - \mathbf{R}' = \mathbf{R}''$$

$$\psi(\mathbf{r}) = \sum_n b_n \varphi_n(\mathbf{r})$$

$$H\psi(\mathbf{r}) = (H_{\text{at}} + \Delta U(\mathbf{r}))\psi(\mathbf{r}) = \varepsilon(\mathbf{k})\psi(\mathbf{r})$$

$$\int d\mathbf{r} \phi_m^*(\mathbf{r}) \times$$



$$(\varepsilon(\mathbf{k}) - E_m) \int \phi_m^*(\mathbf{r}) \psi(\mathbf{r}) d\mathbf{r} - \int \phi_m^*(\mathbf{r}) \Delta U(\mathbf{r}) \psi(\mathbf{r}) d\mathbf{r} = 0$$

$$\int \phi_m^*(\mathbf{r}) H_{\text{at}} \psi(\mathbf{r}) d\mathbf{r} =$$

$$\int (H_{\text{at}} \phi_m(\mathbf{r}))^* \psi(\mathbf{r}) d\mathbf{r} = E_m \int \phi_m^*(\mathbf{r}) \psi(\mathbf{r}) d\mathbf{r}$$

$$\int \phi_m^*(\mathbf{r}) \phi_n(\mathbf{r}) d\mathbf{r} = \delta_{mn}$$

Ortho-normal conditions

$$(\epsilon(\mathbf{k}) - E_m) b_m + (\epsilon(\mathbf{k}) - E_m) \sum_n \left( \sum_{\mathbf{R} \neq 0} \int \phi_m^*(\mathbf{r}) \phi_n(\mathbf{r} - \mathbf{R}) e^{i\mathbf{k} \cdot \mathbf{R}} d\mathbf{r} \right) b_n = \\ + \sum_n \left( \int \phi_m^*(\mathbf{r}) \Delta U(\mathbf{r}) \phi_n(\mathbf{r}) d\mathbf{r} \right) b_n + \sum_n \left( \sum_{\mathbf{R} \neq 0} \int \phi_m^*(\mathbf{r}) \Delta U(\mathbf{r}) \phi_n(\mathbf{r} - \mathbf{R}) e^{i\mathbf{k} \cdot \mathbf{R}} d\mathbf{r} \right) b_n$$

Matrix representation       $\mathbf{b} = \{b_n\}$   
 $(m, n)$  component

Overlap integral       $S_{m,n}(\mathbf{k}, \mathbf{R}) = \int \phi_m^*(\mathbf{r}) \phi_n(\mathbf{r} - \mathbf{R}) e^{i\mathbf{k} \cdot \mathbf{R}} d\mathbf{r}$   
 $S_{m,n}(\mathbf{k}) = \sum_{\mathbf{R}} S_{m,n}(\mathbf{k}, \mathbf{R})$

$$(\epsilon(\mathbf{k}) - E_m) S_{m,n} \quad H'_{m,n}(\mathbf{k}) = \sum_{\mathbf{R}} \int \phi_m^*(\mathbf{r}) \Delta U(\mathbf{r}) \phi_n(\mathbf{r} - \mathbf{R}) e^{i\mathbf{k} \cdot \mathbf{R}} d\mathbf{r}$$

$$\epsilon(\mathbf{k}) \mathbf{S} \cdot \mathbf{b} = \mathbf{H} \cdot \mathbf{b}$$

$$H_{m,n} = E_m S_{m,n} + H'_{m,n}$$

$$|\epsilon(\mathbf{k}) \mathbf{S} - \mathbf{H}| = 0$$

Generalized secular equation



Numerically undesirable

# Improvement

---

Orthogonalize atomic orbitals at different sites

$$\int \phi_m^*(\mathbf{r}) \phi_n(\mathbf{r} - \mathbf{R}) d\mathbf{r} = \delta_{mn}$$

Löwdin functions

Wannier functions

$$H'_{m,n}(\mathbf{R}) = \int \phi_m^*(\mathbf{r}) \Delta U(\mathbf{r}) \phi_n(\mathbf{r} - \mathbf{R}) e^{i\mathbf{k}\cdot\mathbf{R}} d\mathbf{r}$$

Treat as fitting parameters



Slater-Koster matrix elements

Standard secular equation

$$\left| (\varepsilon(\mathbf{k}) - E_m) \mathbf{1} - \mathbf{H} \right| = 0$$

Exercise 2: Calculate the TB band of a SC lattice in one dimension, using only  $s$ -orbitals and nearest-neighbor interactions.

Ignore overlap integral.

Plot the result along the  $k_x$  line.

Interpret the band dispersion.

$$\varphi_s(\mathbf{r}) = \sum_R e^{ikR} \phi_s(\mathbf{r} - \mathbf{R})$$



$$(\varepsilon(\mathbf{k}) - E_m)b_s = b_s \left( \int \phi_m^*(\mathbf{r}) \Delta U(\mathbf{r}) \phi_n(\mathbf{r}) d\mathbf{r} \right) + b_n \left( (e^{ika} + e^{-ika}) \int \phi_m^*(\mathbf{r}) \Delta U(\mathbf{r}) \phi_n(\mathbf{r} - \mathbf{R}) d\mathbf{r} \right)$$

$\alpha$

$2 \cos(ka)$

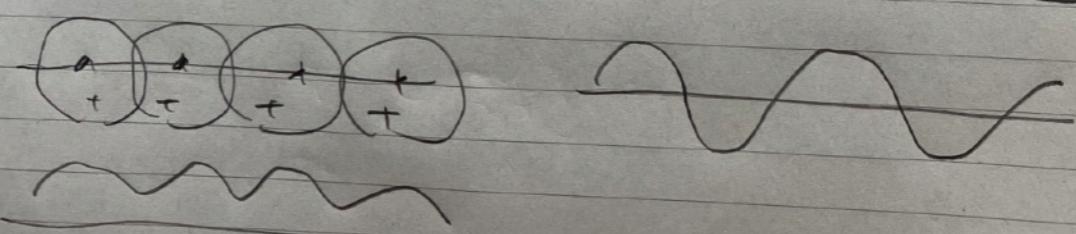
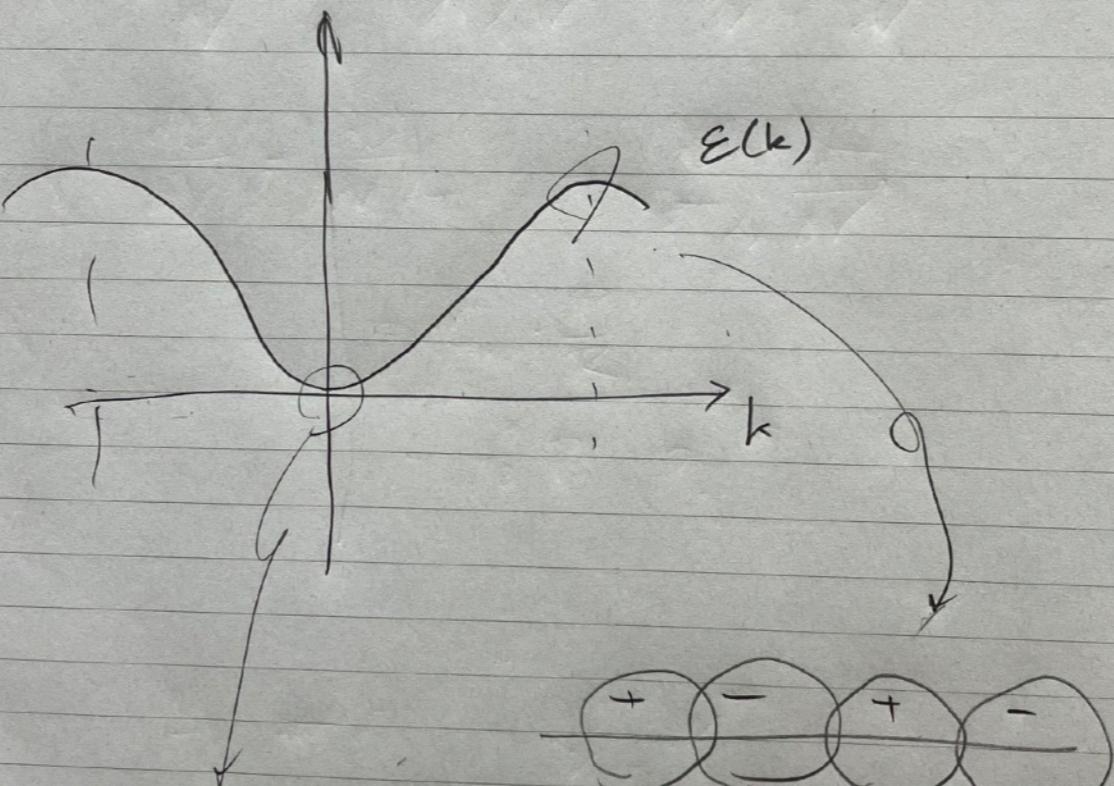
$\gamma$

$$\varepsilon(\mathbf{k}) = E_m + \alpha + 2\gamma \cos(ka)$$

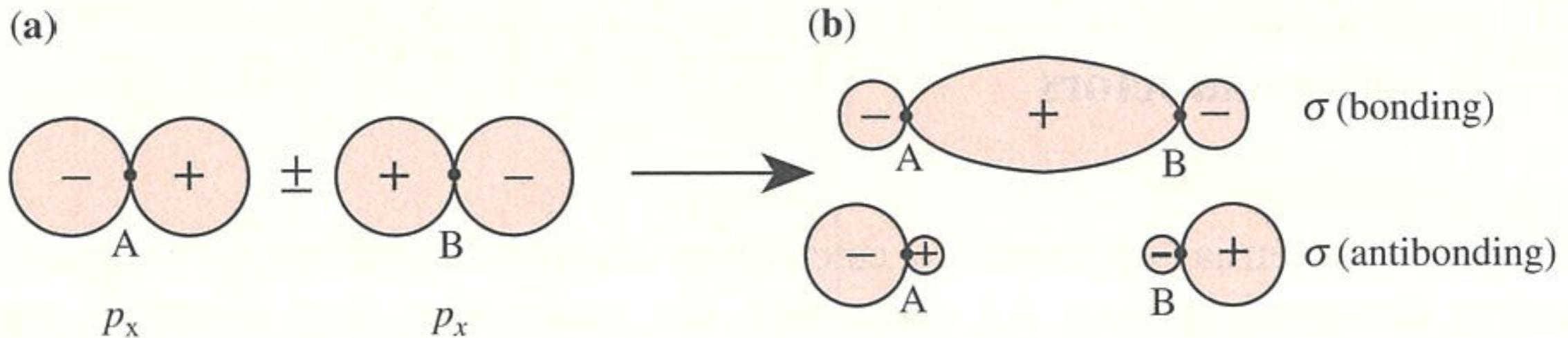
$$E(k) = \underbrace{E_s}_{\text{const}} + \hbar + 2\gamma \cos(ka)$$

$$\gamma = \int \phi(r) \Delta U(r) \phi(r-a) dr$$

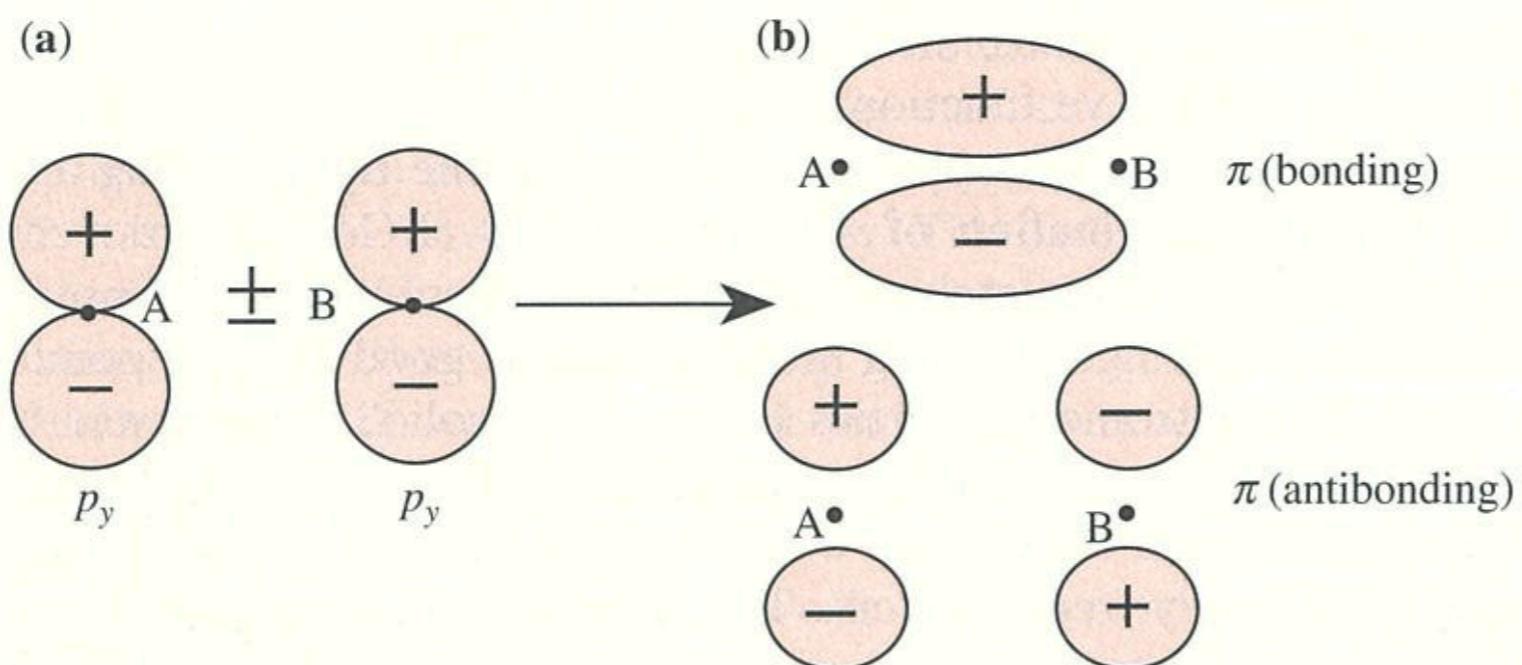
$< 0$  attractive potential.



# Chemical interpretation

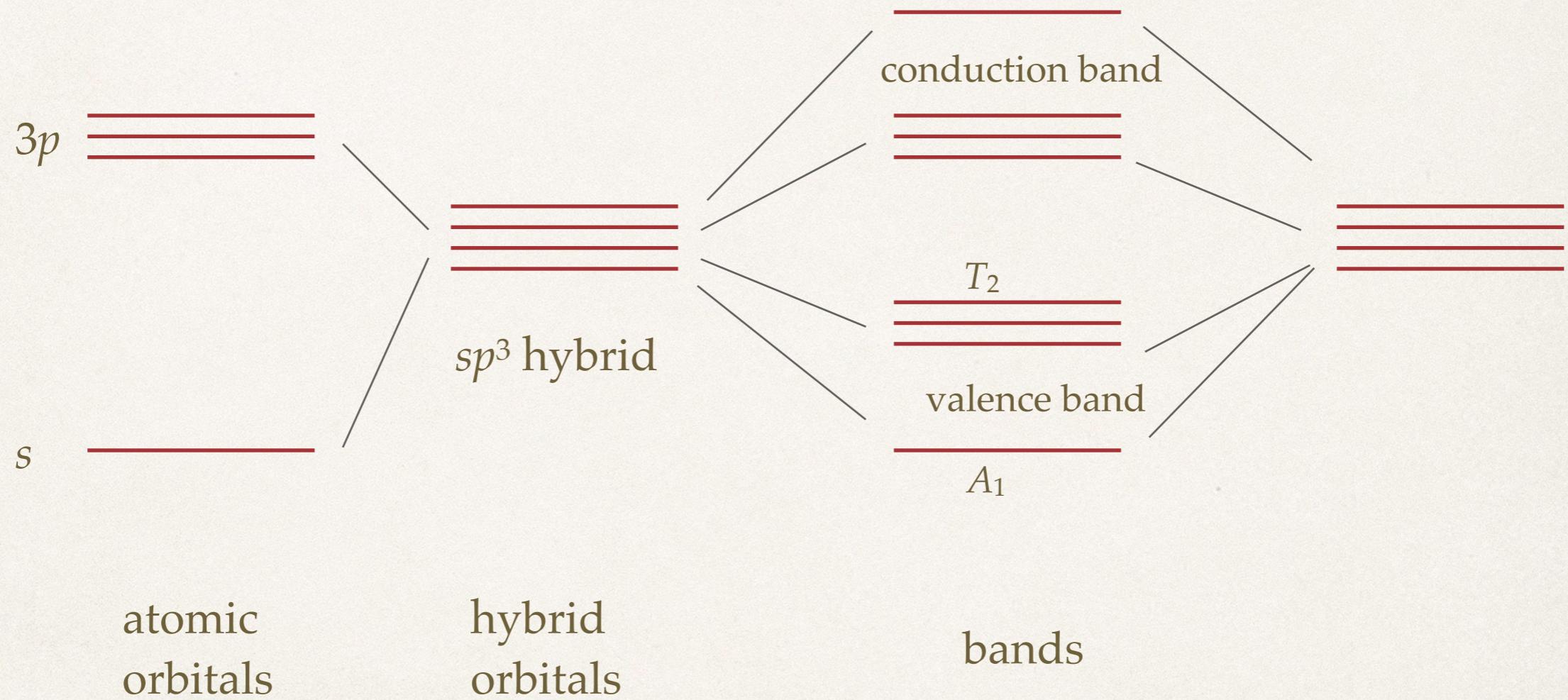


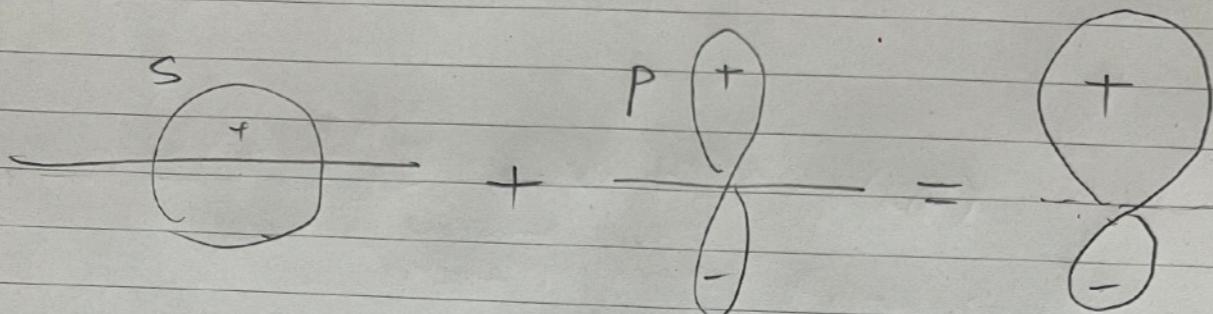
**Fig. 2.18a,b.** Overlap of two  $p_x$  orbitals along the  $x$  axis to form bonding and antibonding  $\sigma$  orbitals



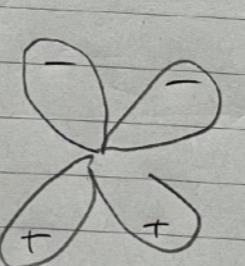
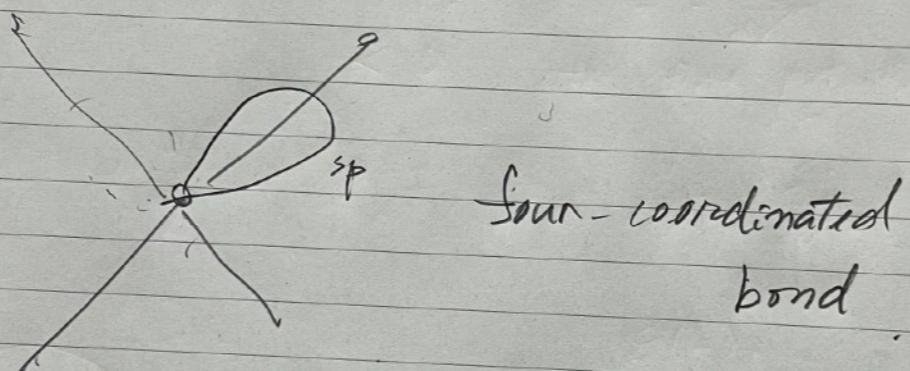
**Fig. 2.19a,b.** Overlap of two  $p_y$  orbitals to form bonding and antibonding  $\pi$  orbitals

# Chemical bond scheme





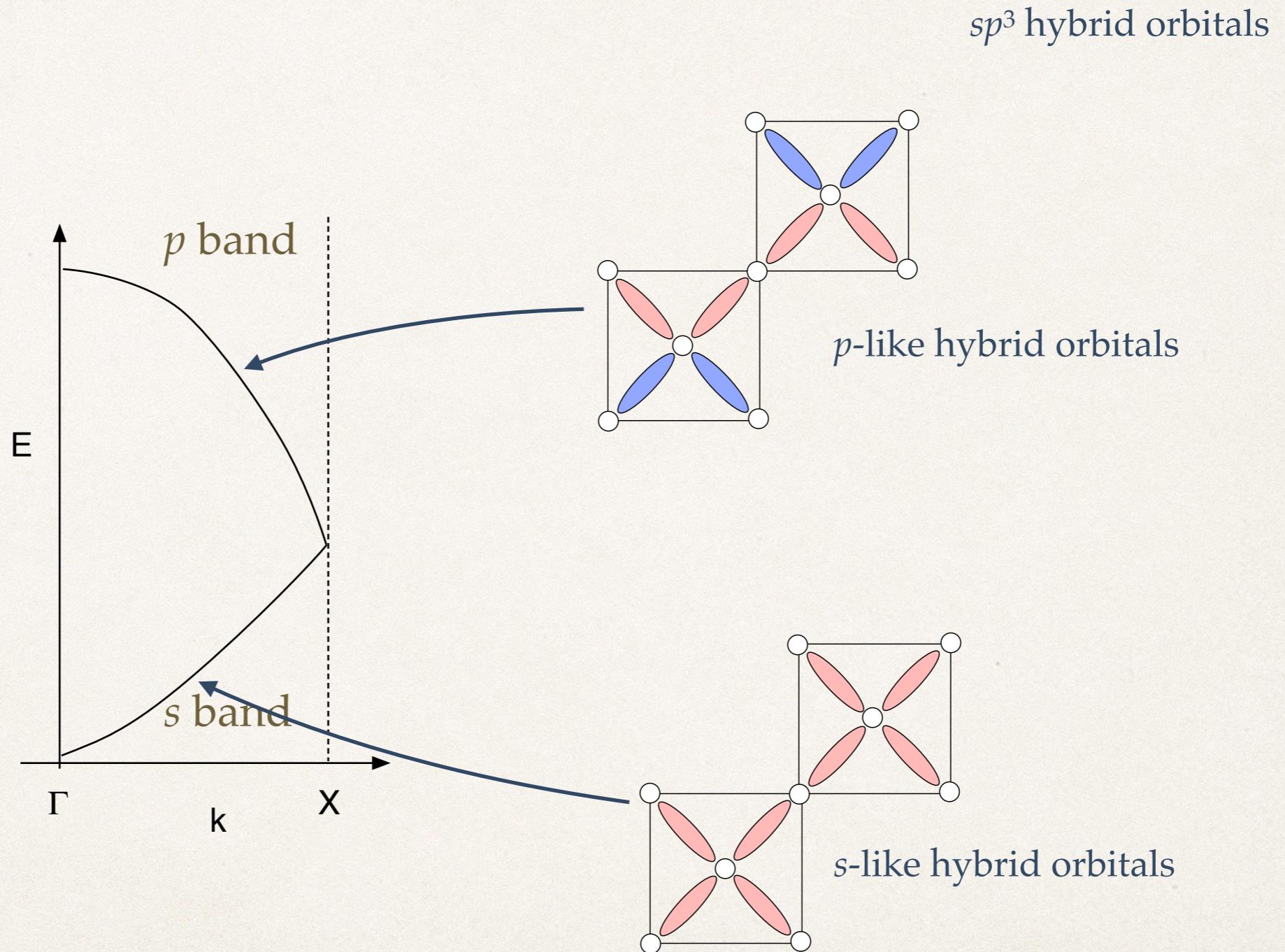
$\hookrightarrow p$  orbital.



s band

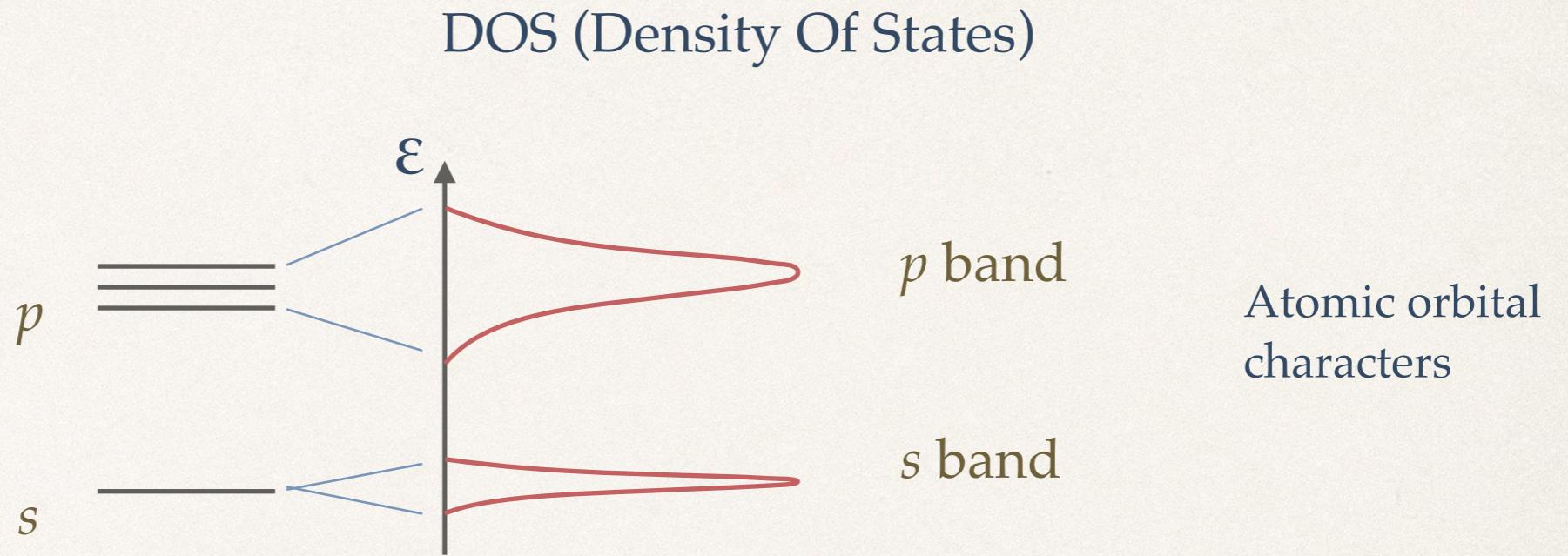
p band

# Correspondence to the band structure

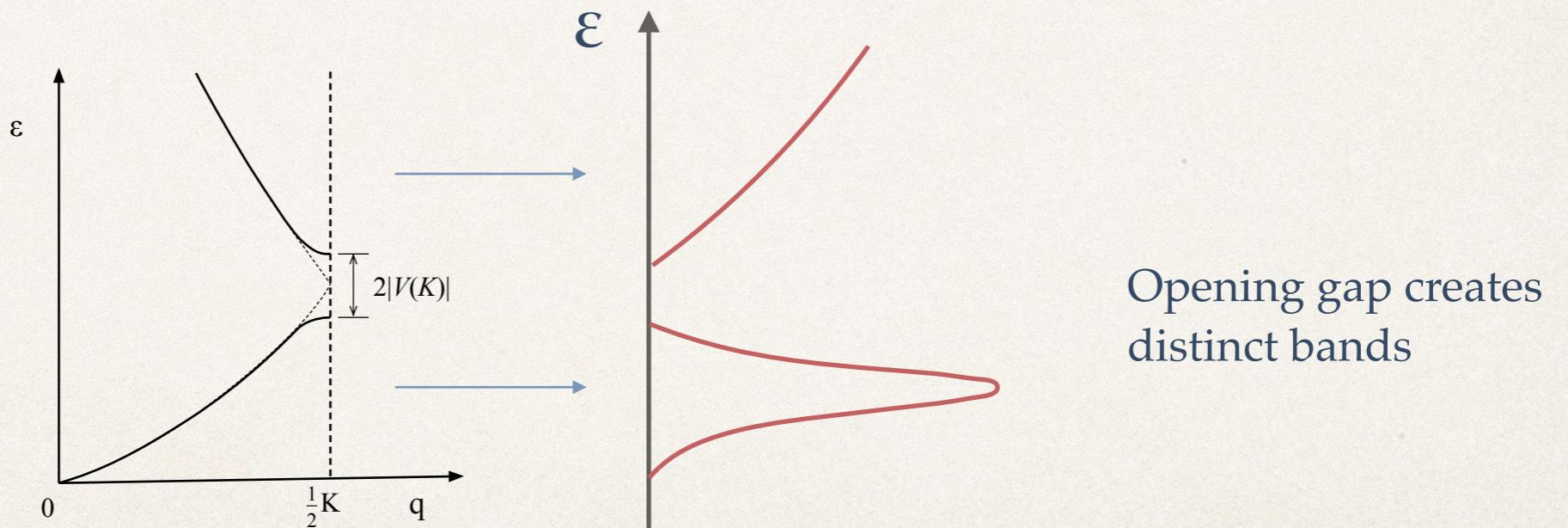


# Blocks of bands

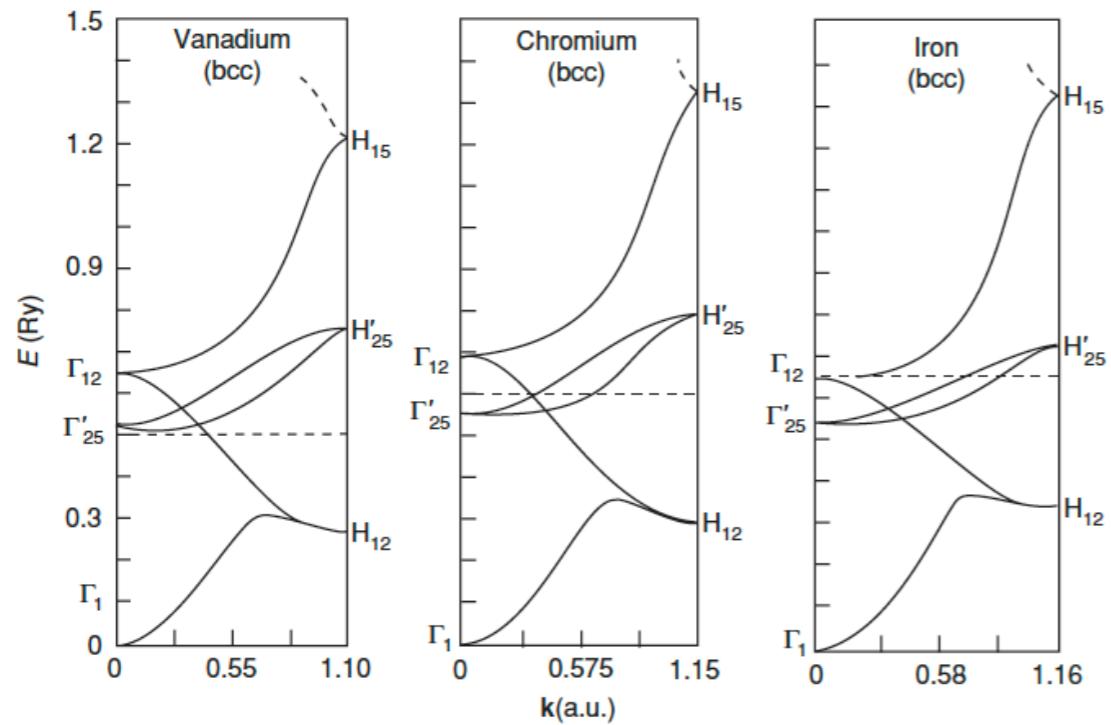
Tight-binding  
model



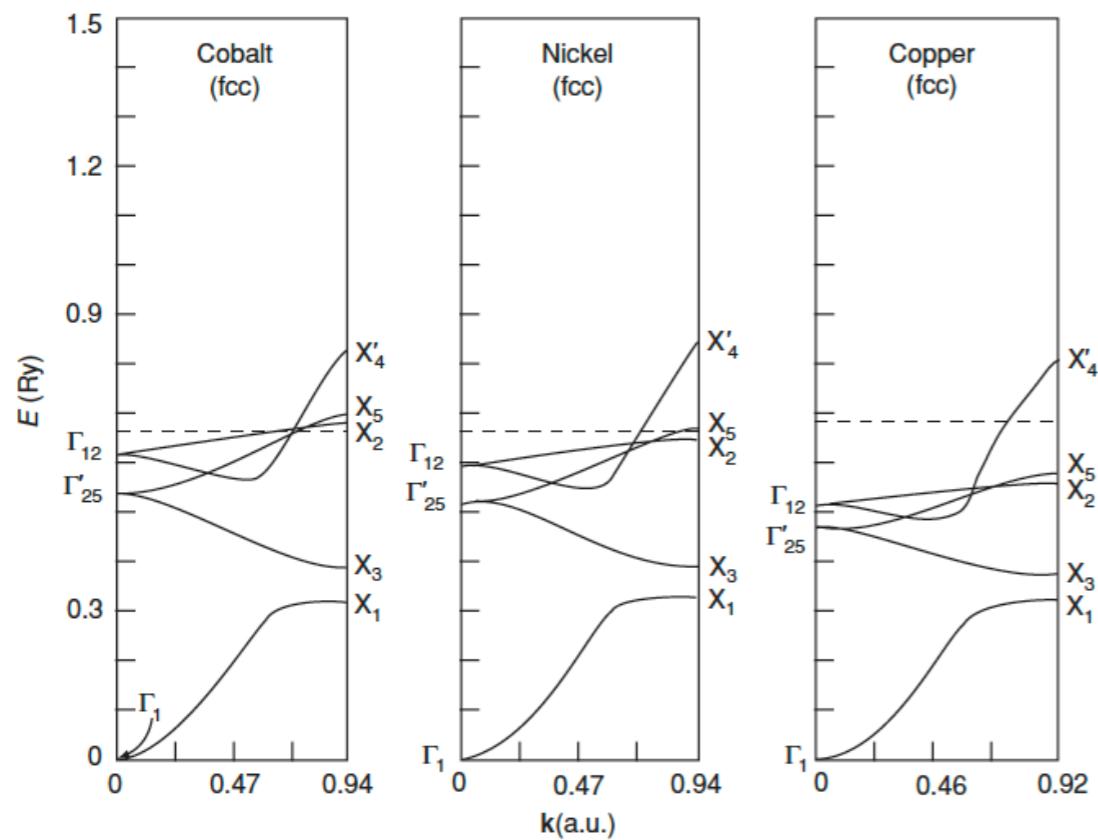
Free-electron  
model



# $d$ bands of transition metals



$s + 5d$  bands



R. M. Martin, *Electronic Structure: Basic theory and practical methods*, Cambridge (2004), p. 321.

## 3.4 Electron dynamics

Semiclassial model

# Effective mass

The  $\mathbf{k} \cdot \mathbf{p}$  method for nondegenerate bands

$$\left[ \frac{p^2}{2m} + \frac{\hbar \mathbf{k} \cdot \mathbf{p}}{m} + \frac{\hbar^2 k^2}{2m} + U(r) \right] u_{n\mathbf{k}}(\mathbf{r}) = E_{n\mathbf{k}} u_{n\mathbf{k}}(\mathbf{r})$$

$$\varphi_{n\mathbf{k}}(\mathbf{r}) = \exp(i\mathbf{k} \cdot \mathbf{r}) u_{n\mathbf{k}}(\mathbf{r})$$

Bloch function

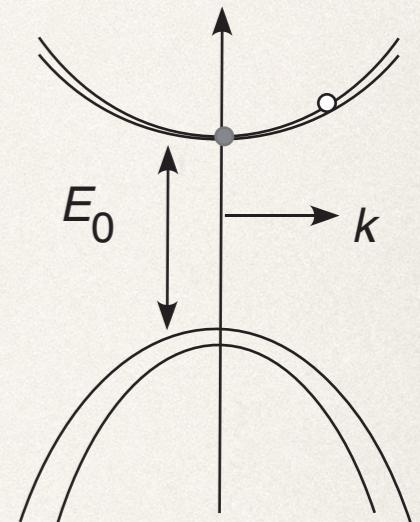
Second-order perturbation

$$E_{n\mathbf{k}} = E_{n0} + \frac{\hbar^2 k^2}{2m} + \frac{\hbar^2}{m} \sum_{n' \neq n} \frac{|\langle u_{n0} | \mathbf{k} \cdot \mathbf{p} | u_{n'0} \rangle|^2}{E_{n0} - E_{n'0}}$$

$$\Delta E = \frac{\hbar^2}{2m^*} k^2$$

$$\frac{1}{m_c^*} = \frac{1}{m} + \frac{2}{m^2 k^2} \sum_{n' \neq n} \frac{|\langle u_{n0} | \mathbf{k} \cdot \mathbf{p} | u_{n'0} \rangle|^2}{E_{n0} - E_{n'0}}$$

$$= \frac{1}{m} + \frac{2 |\langle \Gamma_{1c} | \mathbf{k} \cdot \mathbf{p} | \Gamma_{4v} \rangle|^2}{m^2 E_0 k^2}$$



nonzero  
matrix elements     $\langle \Gamma_{4v} | \mathbf{k} \cdot \mathbf{p} | \Gamma_{1c} \rangle$      $\rightarrow$      $\langle X | p_x | \Gamma_1 \rangle = \langle Y | p_y | \Gamma_1 \rangle = \langle Z | p_z | \Gamma_1 \rangle = iP$

$$P = \frac{2\pi\hbar}{a_0}$$

$$\frac{P^2}{m} \approx 10 \text{ eV}$$

$$\frac{m}{m_c^*} \approx 1 + \frac{2P^2}{mE_0}$$

# Equation of motion

## Equation of motion

$$\mathbf{v}_n = \frac{1}{\hbar} \frac{\partial \epsilon_n(\mathbf{k})}{\partial \mathbf{k}}$$

$$\hbar \dot{\mathbf{k}} = -e \left( \mathbf{E} + \frac{1}{c} \mathbf{v} \times \mathbf{B} \right)$$

$$\epsilon = \frac{\hbar^2}{2m} k^2$$

$$\begin{aligned}\frac{\partial \epsilon}{\partial k} &= \frac{\hbar^2}{m} k \\ &= \hbar v\end{aligned}$$

Almost classical equation!  
except replacing the electron mass by effective mass.

The effective mass has sign.  
is the curvature of  $\epsilon(\mathbf{k})$

## Effective mass (band mass)

$$[\mathbf{M}_n^*]_{ij}^{-1} = \frac{1}{\hbar^2} \frac{\partial^2 \epsilon_n(\mathbf{k})}{\partial k_i \partial k_j}$$

isotropic case

$$\frac{1}{m^*} = \frac{1}{\hbar^2} \frac{\partial^2 \epsilon(k)}{\partial k^2}$$

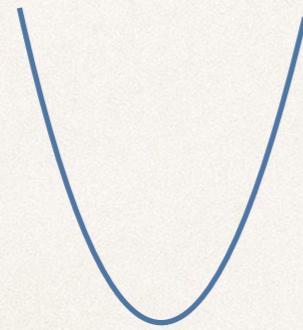
# Electrons and holes

$$\frac{1}{m^*} = \frac{1}{\hbar^2} \frac{\partial^2 \varepsilon(k)}{\partial k^2}$$

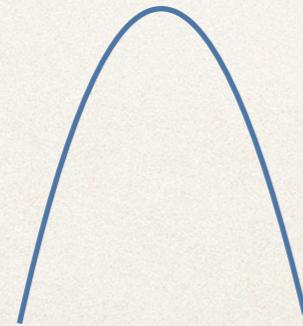
Curvature of band dispersion  $\varepsilon_n(\mathbf{k})$

mobility  $\mu = \frac{e}{m^*} \tau$

scattering time



$m^* > 0$  electron



$m^* < 0$  hole

$$\frac{m}{m_c^*} \approx 1 + \frac{2P^2}{mE_0}$$

matrix element  
 $\langle \Gamma_{4v} | \mathbf{k} \cdot \mathbf{p} | \Gamma_{1c} \rangle$

direct gap

Smaller the band gap is, more faster the electron is.

	Ge	GaN	GaAs	GaSb	InP	InAs	ZnS	ZnSe	ZnTe	CdTe
$E_0$ [eV]	0.89	3.44	1.55	0.81	1.34	0.45	3.80	2.82	2.39	1.59
$m_c^*/m$ (exp)	0.041	0.17	0.067	0.047	0.073	0.026	0.20	0.134	0.124	0.093
$m_c^*/m$ ((2.44))	0.04	0.17	0.078	0.04	0.067	0.023	0.16	0.14	0.12	0.08

# Electrical Conductivity

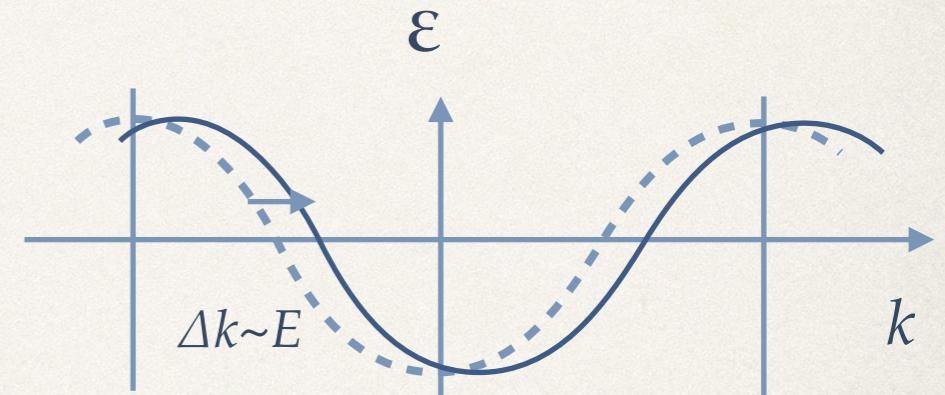
Electron current

$$\mathbf{j}_e = -e \int_{\text{occupied}} \frac{d\mathbf{k}}{4\pi^3} \mathbf{v}(\mathbf{k})$$

$$\mathbf{v}_n = \frac{1}{\hbar} \frac{\partial \epsilon_n(\mathbf{k})}{\partial \mathbf{k}}$$

in periodic structure

$$\int_{\text{zone}} \frac{d\mathbf{k}}{4\pi^3} \mathbf{v}(\mathbf{k}) = 0$$



Fully-occupied band does  
not carry electronic current.

→ Insulator

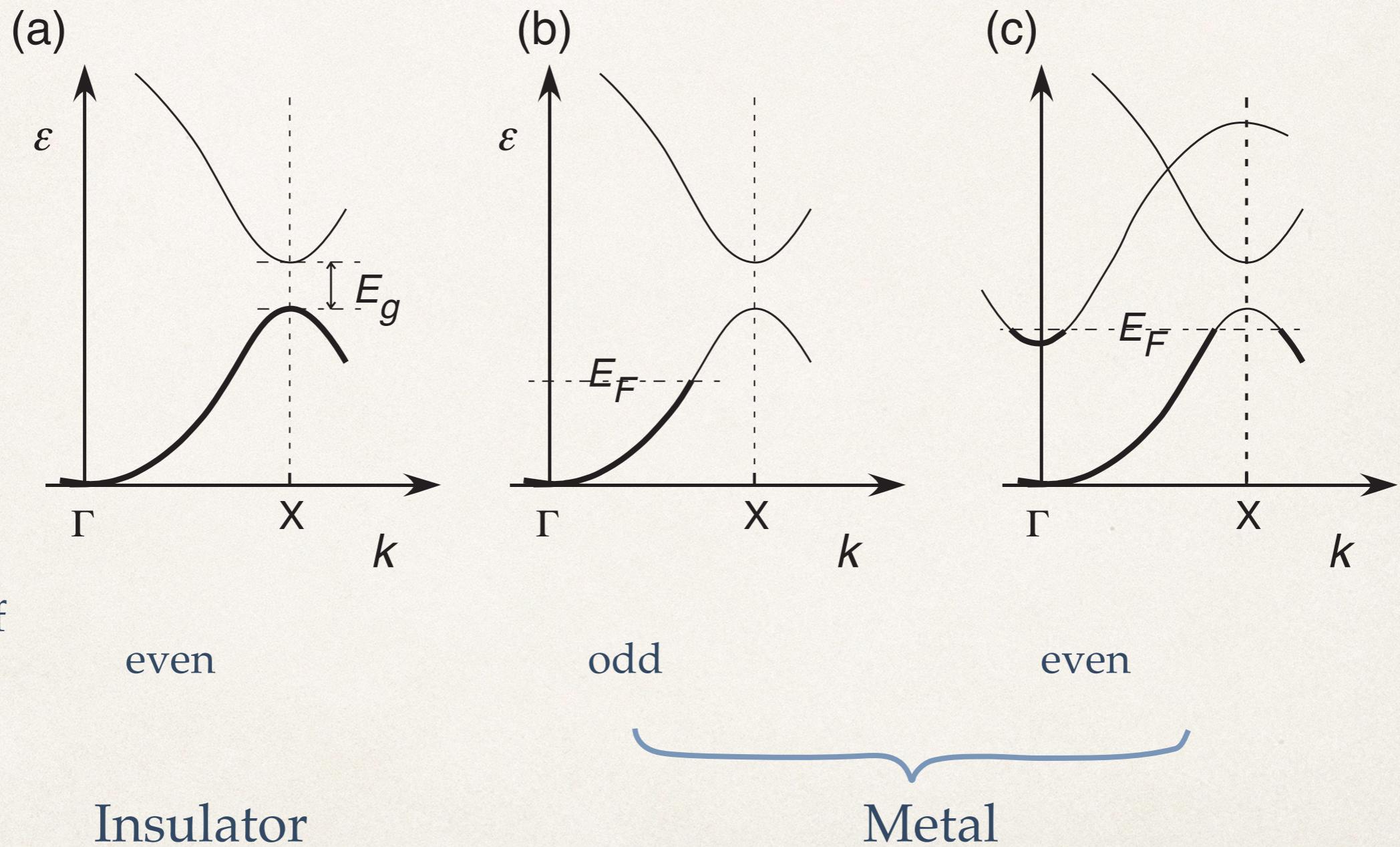
Electron vs. hole

$$\int_{\text{zone}} f = \int_{\text{occupied}} f + \int_{\text{unoccupied}} f = 0$$



$$\mathbf{j}_h = +e \int_{\text{unoccupied}} \frac{d\mathbf{k}}{4\pi^3} \mathbf{v}(\mathbf{k})$$

# Classification of crystals



## 3.5 Success of band theory

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# Classification of crystals

Metal and insulator

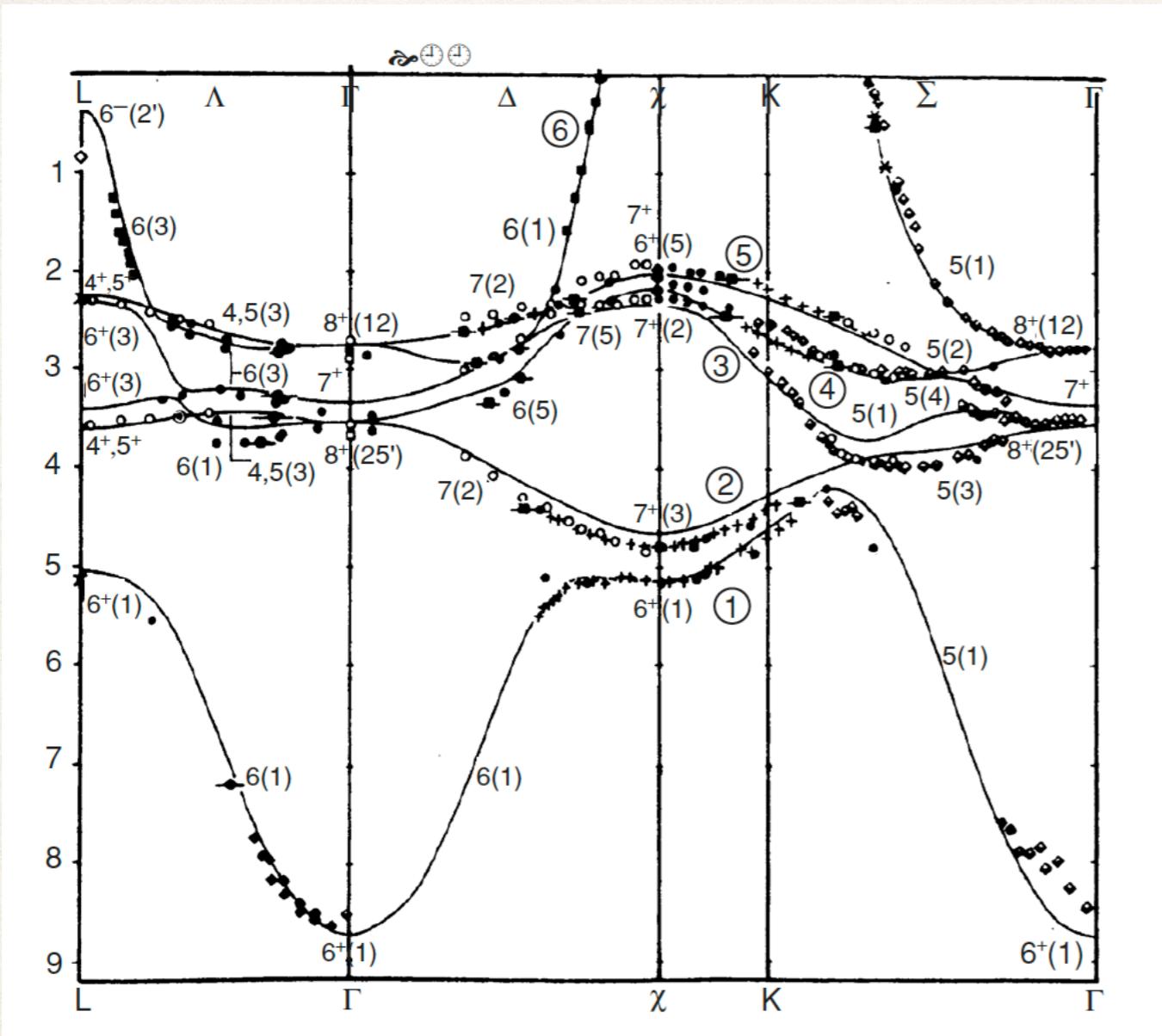
Optical properties

# Conduction characteristics

Electron and hole bands

Mobility

# The band structure of Cu



Calc.

The classic APW calculations  
using the Chodorow potential

G. A. Burdick, Phys. Rev.  
128, 138 (1963)

Exp.

angle-resolved photoemission  
(points)

P. Thiry, et al., Phys. Rev.  
Lett. 43, 82 (1979)